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High Voltage Resistor Series

Web: www.token.com.tw

Email: rfq@token.com.tw

Token Electronics Industry Co., Ltd.

Taiwan: No.137, Sec. 1, Zhongxing Rd., Wugu District,

New Taipei City, Taiwan. 248012

Tel: +886 2981 0109 Fax: +886 2988 7487

China: 17P, Nanyuan Maple Leaf Bldg., Nanshan Ave.,

Nanshan Dist., Shenzhen, Guangdong, China. 518054

Tel: +86 755 26055363



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Terminology & Glossary

► Terminology & Glossary

Terminology & Glossary

Cermet

A cermet resistive element is made from a mixture of glass and metal oxides. The metal oxide is typically RuO_2 or an AgPt alloy. Applying cermet materials to a flat or cylindrical substrate, and then firing them at 850°C produce thick Film resistors. In the electronic industry cermet material is typically called Thick Film paste or ink.

Critical Resistance Value

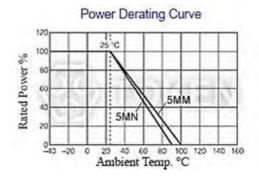
The maximum nominal resistance value at which the rated power can be applied continuously without exceeding the maximum working voltage is the critical resistance value. The rated voltage is equal to the maximum working voltage in the critical resistance value. If the circuit designs permits, the choice of a high Ohmic value resistor or divider network will eliminate this consideration.

Derating Curve

The curve that describes the relationship between the resistors' operating temperature and the maximum value of continuous power permitted at that temperature. If the circuit designs permits, the choice of a high ohmic value resistor or divider network will minimize this consideration and improve the resistor's performance because it will operate at lower power.



The maximum voltage applied continuously to a resistor or a resistor element. The maximum value of the applicable voltage is the rated voltage at the critical resistance value



Typical Derating Curve

or lower. If the circuit designs permits, the choice of a high ohmic value resistor or divider network will improve the resistor's performance because it will operate at lower power.

Noise

Resistive noise can have a devastating effect on low-level signals, charge amplifiers, high gain amplifiers, and other applications sensitive to noise. The best approach is to use resistor types with low or minimal noise in applications that are sensitive to noise. Because of their construction and manufacturing processes.

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Power Rating

Power ratings are based on physical size, allowable change in resistance over life, thermal conductivity of materials, insulating and resistive materials, and ambient operating conditions. For best results, employ the largest physical size resistors at the less than their maximum rated temperature and power. Never use them continuously at their maximum rating unless you are prepared to accept the maximum allowed life cycle changes. If the circuit designs permits, the choice of a high ohmic value resistor or divider network will minimize the power level and improve the resistor's performance as it is operating at a lower power level.

Rated Power

Rated power is the maximum value of power (watts), which can be continuously applied to a resistor at a rated ambient temperature. The basic mathematical relationship is

Equation: Power (watts) = $(Current (Amps))^2 \times Resistance (Ohms)$.

If the circuit designs permits, the choice of a high ohmic value resistor or divider network will minimize the power level and improve the resistor's performance because it is operating at a lower power and temperature level.

Rated Voltage

The maximum voltage applied continuously to a resistor at the rated ambient temperature. Rated voltage is calculated from the following formula, but it must not exceed the maximum working voltage.

Equation: Rated Voltage (V) = (Rated Power (W) × Nominal Resistance Value (Ω)) $^{1/2}$.

High voltage resistors often are potted or operated in oil as the arc over voltage, in air, is approximately 10,000 volts per inch. Token's resistors feature higher voltage ratings due to their high square count and associated design characteristics.

Resistor Tolerance

Resistor Tolerance is expressed as the deviation from nominal value in percent and is measured at 25 °C only with no appreciable load applied. A resistors value will also change with applied voltage (VCR) and temperature (TCR). For networks, absolute resistor tolerance refers to the overall tolerance of the network. Ratio tolerance refers to the relationship of each resistor to the others. It is often practical to specify tight ratio tolerances and loose absolute tolerances.



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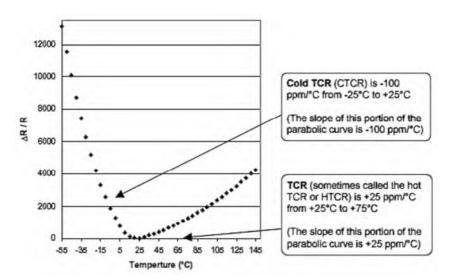
Temperature Coefficient of Resistance (TCR)

The Temperature Coefficient of Resistance (TCR) is expressed as the change in resistance in ppm (0.0001%) with each degree of change in temperature Celsius (°C). For example, a resistor with a TCR of +100 ppm/°C will change +0.1% total over a 10-degree change and +1% total over a 100-degree change.

The TCR value quoted on specification sheets is typically quoted as being referenced at $+25^{\circ}$ C and is the $+25^{\circ}$ C to $+75^{\circ}$ C slope of the TCR curve. TCR is typically not linear, but parabolic with temperature, as illustrated by the accompanying fig-1. Often the circuit designer treats the TCR as being linear unless very accurate measurements are needed. MIL STD 202 Method 304 is often referenced as a standard for measuring TCR. The following formula expresses the rate of change in resistance value per 1° C in a prescribed temperature range:

- TCR (ppm/°C) = $(R R_o) / R_o \times 1 / (T T_o) \times 10^6$
- R: Measured resistance (Ω) at T $^{\circ}$ C; R_o: Measured resistance (Ω) at T_o $^{\circ}$ C
- T: Measured test temperature ($^{\circ}$ C); T_o: Measured test temperature ($^{\circ}$ C)

In the context of a resistor network, this TCR value is called the absolute TCR in that it defines the TRC of a specific resistor element.



Typical Thick Film TCR (Temperature Coefficient of Resistance) Curve

Voltage Coefficient of Resistance (VCR)

The Voltage Coefficient is the change in resistance with applied voltage. This is entirely different and in addition to the effects of self-heating when power is applied. A resistor with a VCR of 100 ppm/V will change 0.1% over a 10 Volt change and 1% over a 100 Volt change. The rate of change in resistance value per 1 Volt in the prescribed voltage range is expressed by the following formula:

- VCR (ppm/V) = $(R_o R) / R_o \times 1 / (V_o V) \times 10^6$
- R: Measured resistance (Ω) at base voltage; V: Base voltage
- R_0 : Measured resistance (Ω) at upper voltage; V_0 : Upper voltage



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Ceramic Resistors (RMCA, RMCB)

Product Introduction

Non-Inductive Enhanced Performance for High Voltage Ignition Applications.

Features:

- Operating Temperature -40° \mathbb{C} ~ 155° \mathbb{C} .
- Resistance Tolerance $K(\pm 10\%)$, $M(\pm 20\%)$.
- Typical resistance range 470 ohm ~ 100 Kohm.
- Replaces 1 and 2 watt carbon composition resistors.
- Suitable for noise suppressor of engine ignition system.
- High peak power, Reliable with non-disconnection failure.
- Rated Wattage up 5W, meets high energy density demands.

The RMCA, RMCB Series MELF type of fixed ceramic resistors from Token Electronics offers automotive designers a compact solution for applications involving high voltages, surges, high peak power, or high-energy pulses. They offer enhanced performance in R-C snubber circuits, high voltage power supplies, and inrush limiters.

Token's RMCA, RMCB series now offers the industry a direct replacement carbon composition resistor based on a bulk resistive element comprising carbon in ceramic filler. Due to the need for higher peak voltages, the RMCA, RMCB range is perfect for vehicle ignition system applications.

Applications:

- Inrush limiters
- R-C snubber circuits
- Vehicle ignition system
- High voltage power supplies



The RMCA, RMCB Voltage Resistors conform to RoHS compliant and lead free. For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact us, or link to Token official website "High Voltage Resistors" to get more information.

Ceramic Composition Resistor Construction:

• Bulk ceramic resistor that consists of a clay, alumina, and ceramic filler that has been blended and pressurized into a resistive core and then covered with a molded outer insulating core.

Replacement Carbon-Composition Resistors:

- Design requirements for custom sizes, surface mount, or special footprints can be met easily.
- In cases where several carbon-composition resistors have been used together in an array to achieve a particular rating, they have been replaced with a single bulk ceramic resistor, frequently at a lower installed cost.

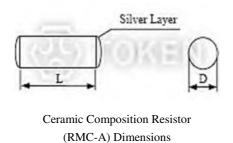
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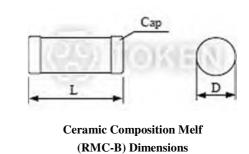


General Specifications

General Specifications (RMCA, RMCB) (Unit: mm)

Model	Ctrilo	Style Deted Wetters		s (Unit: mm)			
Model	Style	Rated Wattage	L	D			
			7 ± 1.5	4.0 ± 0.4			
	A	1	9 ± 1.5	4.0 ± 0.4			
		1	1	1	1	10 ± 1.5	4.0 ± 0.4
	В		11 ± 1.5	4.6 ± 0.5			
RMC	A	2	18 ± 1.5	4.0 ± 0.4			
RIVIC	В		19 ± 1.5	4.6 ± 0.5			
	A	3	24 ± 2.0	4.0 ± 0.4			
	В	3	25 ± 2.0	4.6 ± 0.5			
	A	5	24 ± 2.0	7.0 ± 0.5			
	В	3	25 ± 2.0	7.6 ± 0.5			







Electrical Characteristics

Electrical Characteristics (RMCA, RMCB)

Item		RMCA, RMC	RMCA, RMCB						
Power Rating at 25℃	(W)	1	2	2 3 5					
Operating Temp. Range (°C) -40~155					,				
Resistance Tolerance		K(±10%), M(±20%)							
Resistance Range (Ω)	tance Range (Ω) 470~33K 1K~56K 1K~100K 470~33K								
Max. Working Voltag	ge (V)	300	350	400	500				
T C D (DDM/°C)	-40°C~25°C	-750~3300	-750~3300	-750~3300	-750~3300				
T.C.R (PPM/°C)	25° ℃~ 155° ℃	-750~2600	-750~2600	-750~2600	-750~2600				
Max. Pulse Voltage (I	KV)	8	15	20	25				
Moisture Resistance ((%)	10	10	10	10				

Non-Inductive Performance:

- Chemically inert and thermally stable, the resistors are inherently non-inductive because of their bulk ceramic construction, which allows energy and power to be uniformly distributed through the entire ceramic resistor body with no film or wire to fail.
- The bulk ceramic material also allows simple efficient resistor designs that enable the designer to minimize the resistor package size while providing the required performance and reliability.

Order Codes

Order Codes (RMCA, RMCB)

RMC		2W	a	510R			M
Part Nun	nber	Rated Power (W)	Style	Resistance Value (Ω)		Resistan	ce Tolerance (%)
RMC		1W	a Style	510R	510R 510Ω		±10%
		2W	b Style	5K1	5.1ΚΩ	M	±20%
		3W		51K	51ΚΩ		
		5W		68ΚΩ			

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High Voltage Metal Ceramic Resistor (RMCC)

▶ Product Introduction

Metal Ceramic Resistor is The Way Allows Energy and Power to be Uniformly Distributed.

Features:

- Operating Temperature -40° \mathbb{C} ~ 155° \mathbb{C} .
- Resistance Tolerance $K(\pm 10\%)$, $M(\pm 20\%)$.
- Typical resistance range 470 ohm ~ 100 Kohm.
- Replaces 1 and 2 watt carbon composition resistors.
- Suitable for noise suppressor of engine ignition system.
- High peak power, Reliable with non-disconnection failure.
- Rated Wattage up 5W, meets high energy density demands.

Applications:

- Radar, Motor Drives, Broadcast Transmitters,
- X-Ray, Lasers, Medical Defibrillators,
- Dynamic Braking, Soft-start/Current-limit,
- Snubber Circuits, Dummy Loads, Energy Research,
- RF Amplifiers, Semiconductor Process, Power Conditioning.

Following market demands, Token Electronics provided an extent of Bulk Ceramic Composition RMCA, RMCB Series to RMCC Series. The cap and lead assemblies are pressed onto the RMCC resistor core, finishing the resistor and providing rugged terminal attachment.

Token Surge Resistors - RMCC Series are primarily designed for high voltage, power charging/discharging circuits, surge energy applications and conform to the RoHS directive and Lead-free. For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact us,



or link to Token official website "High Voltage Resistors" to get more information.

Bulk Ceramic Construction:

• Bulk metal ceramic resistors that consists of a clay, alumina, and ceramic filler that has been blended and pressurized into a resistive core and then covered with a molded outer insulating core.

Replacement Carbon-Composition Resistors:

- Design requirements for custom sizes, surface mount, or special footprints can be met easily.
- In cases where several carbon-composition resistors have been used together in an array to achieve a particular rating, they have been replaced with a single bulk ceramic resistor, frequently at a lower installed cost.

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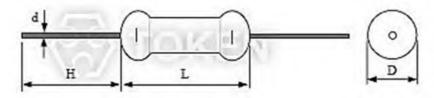
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General Specifications

General Specifications (RMCC)(Unit: mm)

Model	Rated		Dimensions (mm)				
Wiodei	Style	Wattage	L	D	Н	d	
	С	1	11±1.5	4.8±0.5	25±2	0.8±0.05	
RMC	С	2	19±1.5	4.8±0.5	25±2	0.8±0.05	
RIVIC	С	3	25±2.0	4.8±0.5	25±2	0.8±0.05	
	С	5	25±2.0	7.8±0.5	30±3	1.0±0.05	



Bulk Ceramic Composition Resistors (RMCC) Dimensions

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Electrical Characteristics

Electrical Characteristics (RMCA, RMCB)

Item		RMCC							
Power Rating at 25°	C (W)	1	2	3	5				
Operating Temp. Ra	ange (°C)	-40~155	-40~155						
Resistance Tolerance K (±10%), M (±20%)									
Resistance Range (5	2)	470~33K	1K~56K	1K~100K	470~33K				
Max. Working Volta	age (V)	300	350	400	500				
T C D (DDM/°C)	-40°C ~25°C	-750~3300	-750~3300	-750~3300	-750~3300				
T.C.R (PPM/°C)	25°C~155°C	-750~2600	-750~2600	-750~2600	-750~2600				
Max. Pulse Voltage	(KV)	8	15	20	25				
Moisture Resistance	(%)	10	10	10	10				

Non-Inductive Performance:

- Chemically inert and thermally stable, the resistors are inherently non-inductive because of their bulk ceramic construction, which allows energy and power to be uniformly distributed through the entire ceramic resistor body with no film or wire to fail.
- The bulk ceramic material also allows simple efficient resistor designs that enable the designer to minimize the resistor package size while providing the required performance and reliability.

Order Codes

Order Codes (RMCC)

RMC	2W	c		51K		K
Part Number	Rated Power (W)	Style	Resistance Value (Ω)		Resistan	ce Tolerance (%)
RMC	1W	c Style	510R 510Ω		K	±10%
	2W		5K1	5.1ΚΩ	M	±20%
	3W		51K	51ΚΩ		
	5W		68K	68ΚΩ		

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High Voltage Ceramic Resistors (RMCD)

Product Introduction

Bulk Ceramic Tubular Resistor Offers Higher Energy Power Dissipation & Higher Voltage Withstand.

Features:

- Peak voltage up to 74 KV, Power (W) up to 100W.
- Typical resistance range 75 ohm ~ 1 Kohm.
- Resistance tolerance $K(\pm 10\%)$.
- Inductance only 0.4µH max.
- Heavy load characteristics.

Applications:

- X-Ray, Lasers, Medical Defibrillators,
- Dynamic Braking, Soft-start/Current-limit,
- Radar, Motor Drives, Broadcast Transmitters,
- Snubber Circuits, Dummy Loads, Energy Research,
- RF Amplifiers, Semiconductor Process, Power Conditioning.

Power High Voltage Dividers and Resistors Type RMCD extend Token Electronic's advanced proprietary high voltage resistor technology to larger devices than have previously been available on the market.

The RMCD is the bulk non-inductive ceramic tubular resistor. Because of the larger volume of resistive material, these resistors are capable of handling significantly higher pulsed power than their wire wound or metal film counterparts, making them suitable for rapid energy dumping and high energy pulse work.



This RMCD offer higher average power dissipation while retaining the advantages of high surge energy, high voltage withstand, and non-inductance. It is especially useful in RF applications such as transmitters and modulators, where the tube configuration provides more effective convection cooling.

In addition, this RMCD HV resistor and divider provide high peak voltage and power energy combined with extremely high working voltage. These specifications can provide important improvements in performance in many types of advanced electronic systems, including TWT power supplies, radar systems, X-ray systems, analytical equipment and high resolution CRT displays.

Token will also produce devices outside these specifications to meet customer requirements, with comprehensive application engineering and design support available for customers worldwide. For complete information on quantity price and delivery, please contact our Sales Office, or link to Token official website "High Voltage Resistors" to get more information.

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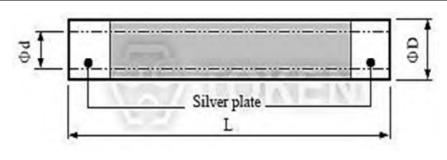
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▶ General Specifications

General Specifications (RMCD) (Unit: mm)

Туре	Dimensions (Unit: mm)		Resistance	Tolerance	Energy	Peak Voltage	Power			
	L±3.0	ΦD±2.0	Φd±2.0	(Ω)	(%)	(KJ)	(KV)	(W)		
RMCD-100	305	25.4	15.5			30	75	100		
RMCD-90	250	25.4	15.5			25	60	90		
RMCD-70	200	25.4	15.5 75~1K	±10	20	45	70			
RMCD-50	150	25.4	15.5			15	30	50		
RMCD-35	100	25.4	15.5			10	15	35		



Tubular High Voltage Resistors (RMCD) Dimensions

▶ Electrical Characteristics

Electrical Characteristics (RMCD)

Туре	Power Rating	Temperature Coefficient	Resistivity	Specific Heat	Inductance	Density	Max. Operating Temperature
RMCD	35 ~ 100W	-500 ~-1500PPM/℃	5~80Ω·cm	2J/cm ³ ⋅°C	0.4μH max	2.25g/cm ³	220°C max

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Order Codes

Order Codes (RMCD)

RMCD	100W	100R			K	S	В	
Part Number	Rated Power (W)	Resistance Value (Ω)		Resistance Tolerance (%)		Silver plate terminal		Color
RMCD	35W	82R	82Ω	K	±10%		В	black
	50W	100R	100Ω					
	70W	470R	470Ω					
	90W	820R	820Ω					
	100W	1K	1ΚΩ					

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High Frequency Resistor (RY31A)

▶ Product Introduction

A Perfect Choice for High Frequency RF Circuit Designs

Features:

- Special Oxide Film technology
- Speciality product for RF applications
- Low-inductance non-helical trimmed product
- Lead (Pb)-free and RoHS compliant

Applications:

- Telecommunication equipment
- Industrial electronics

RY31A specialty MELF Non-Inductive Resistors combines the advanced pulse load capability and the suitability for RF applications in a single component.

They are the perfect choice in RF high frequency circuit designs where the parasitic inductance of regular, helical trimmed resistors cannot be accepted, but where also pulse energies apply. Typical applications are in the fields of telecommunication equipment and industrial electronics.



RY31A - High Frequency Metal Oxide Film Resistor, with the

inner and outer surfaces coated with a special glass, features higher thermal resistance and larger electric power capacity for the compact volume. Unlike conventional wire wound type, the volumetric resistance will provide superior stability versus frequency and excellent durability against transient voltage. RY31A is suitable for the application with large current as well as high frequency circuit.

In very low resistance values, between 1.0 and 100 ohm, these are available in rated wattage 10W, 25W, 50W, 100W, and 150W packages.

The High-Frequency RY31A Series is RoHS compliant and lead free. For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact our Sales Office, or link to Token official website "High Voltage Resistors" to get more information.

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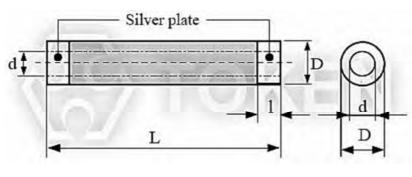
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Electrical Characteristics

Electrical Characteristics (RY31A)

Rated power (W)	T.C.R (PPM/°C)	Resistance range (Ω)	Tolerance (%)	Pulse test voltage (KV)	Ambient Temp.(70°C Full Power)	D max. (mm)	L max. (mm)	d max. (mm)	l max. (mm)
, ,		50 3.2		A 15 1	77	Т 10.7			
10		75		4		Ф 15.1	77	Ф 10.7	5±0.5
25		50		5			121	Ф17.9	10±1
25	(20 %G	70		6.5		Ф 25.1	121		
50	(+20°C	50	±5(J)	7.5	-55℃~		162		
50	~+125°€) ±400	75	±10(K)	8.7	+125°℃		102		
100	2100	50		11			202		12±1
100		75		12.5		Ф 35.1	202	Ф23.1	12±1
150		50		12.5			302		20+2
130	150	75		12.5					20-1



RF Non-Inductive (RY31A) Dimensions

- Note: Request resistance within $1\sim100\Omega$, please contact Token Sales.
- The resistors with the standard resistance values as showed as above. will be supplied with a shorter delivery.

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Order Codes

Order Codes (RY31A)

RY31A	10W		50R		K
Part Number	Rated Power (W)	Resistance Value (Ω)		Resista	ance Tolerance (%)
RY31A	10W	51R	51Ω	J	±5%
	25W	56R	56Ω	K	±10%
	50W	62R	62Ω		
	100W	68R	68Ω		
	150W	75R	75Ω		

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High Voltage Hermetic Resistor (RH1)

▶ Product Introduction

Hermetic Resistors Lead to a High Ohmic Resistance Values.

Features:

- High Resistance Range $1 \times 10^7 \sim 1 \times 10^{12} (\Omega)$.
- Resistance Tolerance (J±5%) (K±10%).
- Glass vacuum sealed hermetic resistors.
- Stability temperature and voltage.
- Metal Glaze resistive elements.

Applications:

- Ultra-High Vacuum Applications.
- Surge Protection and Voltage Divider.
- Mains Protection and Discharge Path Resistor.
- Current Pulse Limiters and Pulse Load Equipments.
- Micro Current Circuit Measurement, Medical Instrumentation.

Token Hi-Meg Hermetically Sealed Resistors are designed for use in electrometer circuits where a high order of performance is required an extended period of time under adverse environmental conditions.

The RH1 metal glaze resistor is disclosed as being encapsulated in a glass tube, the enclosure being hermetically sealed to conductive caps mounted on the resistor ends. The metal glaze film of the resistance path of the resistor is protected from thermal damage during heat sealing by spacing the resistance path from the conductive caps and providing an electrical path there between in the form of an extended termination.



By being vacuum sealed in a glass envelope with its resistance glaze glass characteristic, these high resistance resistors are suitable for ultra-high vacuum applications, micro current circuit measurement, and pulse load equipment.

These RH1 Series features a high degree of stability and accuracy, and operate at this high performance level for long-term stability.

For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact us, or link to Token official website "<u>High Voltage Resistors</u>" to get more information.

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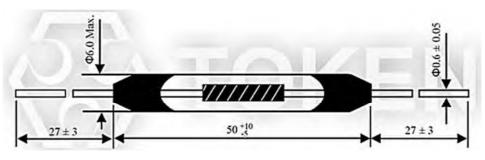
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Dimensions & Specification

Dimensions & Specification (RH1) (Unit: mm)

Resistance Range	$1 \times 10^7 \sim 1 \times 10^{12} (\Omega)$
Resistance Tolerance	$(J\pm 5\%) (K\pm 10\%)$
Operating Temperature	-55 ~ +125
Temperature Coefficient	±500PPM/ (-55~+125°C)
Damp Heat	$\Delta R \le \pm (5\%R + 0.1\Omega)$
Working Voltage	1000V
Rated Power	1/2 W



Hermetic High Resistance High-Megohm Resistors (RH1) Dimensions (Unit: mm)

Cleaning & Handling

Cleaning & Handling (RH1)

Hermetic High-Megohm Resistor Cleaning & Handling:

- It should be handled by the leads, unless gloves are worn.
- If cleaning should become necessary, use isopropyl alcohol and lightly wipe dry with lint free tissues.
- These glass encapsulated (hermetic) resistors with high resistance value is required extraordinary cleanliness.
- Fingerprints on the surface of the resistor will attract contaminants and moisture, which will cause a parallel resistance path, reducing the resistance value of the device.

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Order Codes

Order Codes (RH1)

RH1		1T	J		
Part Number	Resi	stance Value (Ω)	Resistance Tolerance (%)		
RH1	1T 1TΩ		J	±5%	
	10T	10ΤΩ	K	±10%	
	100T	100ΤΩ			

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High Voltage Surge Resistor (RI80)

Product Introduction

Serpentine Pattern Design Achieves High Power Voltage Resistors (RI80).

Features:

- Rated Wattage from 1W to 300W.
- Max Working Voltage from 10KV to 35KV.
- Resistance Tolerance G(±2%), J(±5%), K(±10%).
- Temperature Coefficient: 200 ppm/°C to 400 ppm/°C.
- High Resistance Range from 1 Megohm to 1,000 Megohms.

Applications:

- Impulse voltage generators,
- Arc furnace damping, Energy research,
- Pulse modulators, Radar Pulse-forming networks,
- Capacitor crowbar circuits, High voltage snubber circuits,
- X-ray/imaging equipment, and EMI/lightning supression.

The tubular RI80 high voltage precision resistors were specifically designed for general purpose high voltage systems in industrial. The RI80 uses Token's proprietary thick film Metal Glaze resistive element and Serpentine Pattern Design which provides ideal cost efficient, stability, precision and high voltage characteristics for a wide range of measurement, voltage divider circuits, and control functions in high voltage power electronics applications.



Token RI80 Precision Voltage Resistors are able to absorb large amounts of energy at high voltage while remaining

non-inductive and heavy load characteristics. The RI80 conforms to the RoHS directives and Lead-free. Customed design and tighter tolerances are available on request.

By utilizing specific ceramic core materials with optimum processing, Token are able to control, very tightly in manufacturing, the important ultra-stable performance parameters in operating temperatures from -55 $^{\circ}$ C to +70 $^{\circ}$ C.

(RI80) can handle up to 35KV voltage. This unique process is offered in specific resistance values in a wide variety of sizes and terminations. The extraordinary operating stability of the Type RI80 resistors will improve the performance of your high voltage system.

The RI80 Precision Voltage Series is for customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact our sales, or link to Token official website "<u>High Voltage Resistors</u>" to get more information.

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General Specifications

General Specifications (RI80) (Unit: mm)

Part	Rated		Din	nensions	s (Unit:	:mm)	Resistance	Temp	Max Working	Operating	Resistance			
Number	Wattage (W)	Style	Lmax	Dmax	I	d	Range (Ω)	Coefficient (10-6/°C)	Voltage (KV)	Temp (°C)	tolerance (%)			
RI80-1	1	a	30±2	9±1	30±3	0.7±0.1			10					
RI80-2	2	a	50±2	9±1	30±3	0.7±0.1						15		
RI80-3	3	a	65±2	9±1	30±3	0.7±0.1	1R ~ 1T				15		1	
RI80-5	5	a	100±2	9±1	30±3	1±0.1	1K ~ 11	1R≤R<1G,	25		F(±1%)			
RI80-10	10	a	144±2	11±1	30±3	1±0.1		(±100ppm)	30					
RI80-10	10	b/c	147±2	11±1	6±1	M4		1G≤R<10G,	30					
RI80-20	20	b/c	116±2	17±1	10±1	M6		(±200ppm)	30					
RI80-25	25	b/c	116±2	19±1	10±1	M6			30	30	~	G(±2%) J(±5%)		
RI80-30	30	b/c	116±2	19±1	10±1	M6	1D 1C	10G≤R<100G,	30	+70°C	$K(\pm 10\%)$			
RI80-50	50	b/c	116±2	21±1	10±1	M6	1R ~ 1G	(±300ppm)	30		, , ,			
RI80-80	80	b/c	130±2	27±1	10±1	M6		100G≤R≤1T,	30					
RI80-100	100	b/c	160±2	27±1	10±1	M6		(±500ppm)	35					
RI80-150	150	b/c	210±2	27±1	10±1	M6	10		35					
RI80-200	200	b/c	260±2	27±1	10±1	M6	1R ~ 200M	35						
RI80-300	300	b/c	310±2	33±1	10±1	M6	2001		35					

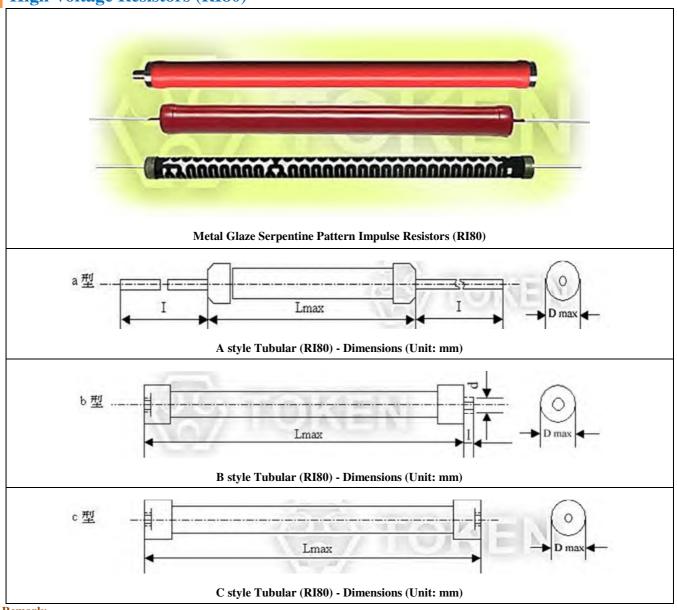
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Construction & Dimensions

High Voltage Resistors (RI80)



- Rated continuous Working Voltage (RCWV) shall be determined from RCWV = $\sqrt{\text{Power Rating} \times \text{Resistance Value}}$ (Ω)
- When RCWV ≥ Max. Working Voltage listed above, RCWV = Max. Working Voltage.

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Advance Technique

Advance Technique of Non-Inductive & Serpentine Pattern (RI80)

Non-Inductive Performance:

- RI80 Non-Inductive Design which uses a serpentine resistive pattern that offers for zigzagging lines to carry current in opposite directions, thereby achieving maximum neutralization of flux fields over the entire length of the resistor.
- This efficient non-inductive construction without derating of any performance advantages is ideal for applications where high frequency is required.



Serpentine Pattern Screen Printing Design:

- Type High Voltage RI80 Precision Resistors combine Token's Non-Inductive serpentine pattern, high thru-put screen printed silicone coating.
- The alignment of the gap in the serpentine resistor pattern with the gap in the coating pattern provides a complete encapsulation of the resistor element.
- The cap and lead assemblies are pressed onto the resistor core, finishing the resistor and providing rugged terminal attachment.

Order Codes

High Voltage Resistors (RI80)

RI80	1W	a	51M		G	
Part Number	Rated Power (W)	Style	Resistance Value (Ω)		Resistance Tolerance	
RI80	1W	a Style	5M1 5.1MΩ		(%)	
	2W	b Style	51M	51ΜΩ	G	±2%
	3W	c Style	510M	510ΜΩ	J	±5%
	5W				K	±10%
	10W					

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High Voltage Resistors (RI82)

Product Introduction

An Excellent Solution for The High Voltage Trend in Power Impulse Products.

Features:

- Rated Wattage from 0.1W to 30W
- Max Working Voltage from 2KV to 30KV.
- Designs built from customer supplied schematics
- Tough epoxy-based coating and high voltage stability
- Temperature Coefficient: 200 ppm/°C to 300 ppm/°C.
- Resistance Range from 10 Megohm to 100K Megohms (100 Gegaohms).
- Resistance Tolerance F(±1%), G(±2%), J(±5%), K(±10%), and M(±20%).
- Stable cermet resistive element bonded to a high-purity alumina substrate.

Applications:

- X-ray/imaging equipment, Impulse voltage generators,
- Capacitor crowbar circuits, High voltage snubber circuits, Arc furnace damping,
- Pulse modulators, Radar Pulse-forming networks, Energy research, and EMI/lightning supression.
- Applications include power supplies, transformers and any application requiring operation within an environment where high voltages are used.

The High Voltage RI82 Precision Series provides an excellent solution for design engineers looking for a compact product with high-voltage capabilities to enable them to design within the voltage trend for power impulse products.

The RI82 resistors use Token's proprietary thick film Metal Glaze resistive element and Serpentine Pattern Design which provides ideal cost efficient, stability, precision, non-Inductive, and high voltage characteristics for a wide range of measurement, voltage divider circuits, and control functions in high voltage power electronics applications.



By utilizing specific 96 % pure alumina materials with optimum processing, Token are able to control, very tightly in manufacturing, the important ultra-stable performance tolerance $F(\pm 1\%)$, $G(\pm 2\%)$, $J(\pm 5\%)$, $K(\pm 10\%)$, and $M(\pm 20\%)$. Voltage handles up to 30 KV. This unique process is offered in specific resistance values in a wide variety of sizes and terminations. The extraordinary operating stability of the Type RI82 resistors will improve the performance of your high voltage system in precision.

The Precision RI82 High Voltage Series is RoHS compliant and lead free. For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact us, or link to Token official website "High Voltage Resistors" to get more information.

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Chip General Specifications

Chip Type General Specifications (Unit: mm) (RI82)

Part	Rated Wattage	Style	Dimensions (Unit: mm)					Resistance	Temp Coefficient	Resistance Tolerance	Max Working
Number	Number (W)		L Max	S Max	H Max	Ι	D Max	Range (Ω)	(10-6/°C)	Tolerance	Voltage (KV)
RI82-2	2	a	33	8	0.8			10M-1T	≤200	J(±5%)	15
RI82-2	2	a	25	10	0.8			101 v1- 11	≥200	K(±10%) M(±20%)	13
Smax	N N N N N N N N N N										m pating
	A Style I	Dimensio	ns - High	Voltage	Chip Resi	sto	r (RI82)				

Remark:

- Rated continuous Working Voltage (RCWV) shall be determined from RCWV = $\sqrt{\text{Power Rating} \times \text{Resistance Value}}$ (Ω)
- When RCWV ≥ Max. Working Voltage listed above, RCWV = Max. Working Voltage.

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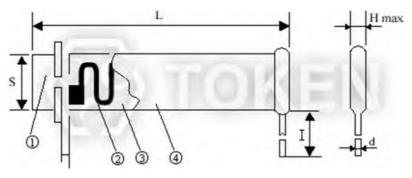
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DIP General Specifications

Dip Type General Specification (Unit: mm) (RI82)

Part	Rated Wattage		Dime	ensions ((Unit: mn	n)	Resistance	Temp Coefficient	Max Working	Resistance	
Number	(w)	L±2	S±2	H Max	I	d±0.1	Range (Ω)	(10-6 /℃)	Voltage(KV)	Tolerance	
RI82-0.125	0.125	8	3.5	2.5	20.0Min	0.56	100M-4.7G		4		
RI82-0.125	0.125	10	5	2.5	24.0Min	0.56	100M-10G		4		
RI82-0.25S	0.25S	10	5	2.5	20.0Min	0.56	10M-1T		4		
RI82-0.25	0.25	22	4	2.5	20.0Min	0.56	100M-10G		4		
RI82-0.25	0.25	25	5	2.5	20.0Min	0.56	100M-10G		10		
RI82-0.5	0.5	35	5	2.5	24.0Max	0.56	100M-10G		15		
RI82-0.5	0.5	41	5	2.5	42.0Max	0.56	10M-1T	1R≤R<1G,	4		
RI82-1	1	25	10	2.5	30.0Max	0.56	100M-10G	(±100PPM)	15		
RI82-1	1	30	8	2.5	30.0Max	0.8	100M-10G	1G≤R<10G,	15	F(±1%) G(±2%) J(±5%) K(±10%) M(±20%)	
RI82-1	1	33	8	2.5	35.0Max	0.56	100M-10G	(±200PPM)	15		
RI82-1	1	38	10	3	45.0Max	0.80	100M-1T	10G≤R<100G,	20		
RI82-2	2	38	10	3	40.0Max	0.80	100M-1T	(±300PPM)	20		
RI82-2	2	45	10	3	45.0Max	0.80	100M-10G	100G≤R≤1T,	20		
RI82-3	3	50	10	3	45.0Max	0.80	100M-1T	(±500PPM)	20		
RI82-3	3	30	15	3	35.0Max	0.80	100M-10G		25		
RI82-3	3	60	10	3	55.0Max	0.80	100M-1T		25		
RI82-5	5	80	20	4	60.0Max	0.80	100M-200M		25		
RI82-10	10	97	23	4	80.0Max	0.80	100M-200M		30		
RI82-20	20	100	35	4	80.0Max	1	100M-200M		30		
RI82-30	30	100	48	4	80.0Max	1	100M-200M		30		
					<u> </u>						



B & C Style Dimensions - High Voltage Dip Type (RI82)

- (1) Silver Palladium Pole
- ② Resistent Film
- 3 96% A1023 Ceramic Base
- b style: Insulate Dielectric Glass; c style: High Temperature Silicone Resin

Remark:

• Rated Continus Working Voltage (RCWW) shall be determined from RCWW = $\sqrt{\text{Power Rating} \times \text{Resistance Value}}$ (Ω) or Max.Working Voltage listed above , whichever two.

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Advance Technique

Advance Technique of Non-Inductive & Serpentine Pattern (RI82)

Non-Inductive Performance:

- Token's RI82 Non-Inductive Design which uses a serpentine resistive pattern that offers for zigzagging lines to carry current in opposite directions, thereby neutralizing maximum of flux fields over the entire length of the resistor.
- This efficient non-inductive construction retains performance advantages and heavy load characteristics which is ideal for high frequency applications.



Serpentine Pattern Screen Printing Design:

- Type RI82 High Voltage Impulse Resistors combine Token's Non-Inductive serpentine pattern, high thru-put screen printed silicone coating.
- The alignment of the gap in the serpentine resistor pattern with the gap in the coating pattern provides a complete encapsulation of the resistor element.
- The lead assemblies are pressed onto the resistor core, finishing the resistor and providing rugged terminal attachment.

Order Codes

Order Codes (RI82)

RI82	0.125W	c		47M		K
Part Number	Rated Power (W)	Style	Resistance Value (Ω)		Resistance Tolerance (%)	
RI82	0.125W	a Style	4M7	4M7 4.7MΩ		±1%
	0.25W	b Style	47M	47ΜΩ	G	±2%
	0.5W	c Style	47M5	47.5MΩ	J	±5%
	1W		470M	470ΜΩ	K	±10%
					M	±20%

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High Voltage Power Resistors (RI85)

Product Introduction

Token High Voltage Resistors (RI85) Break Through 800 Wattage in High Power Applications.

Features:

- Max Working Voltage from 50KV to 100KV.
- Temperature Coefficient $\leq 100 \text{ ppm/}^{\circ}$ C.
- Resistance Range from $100K\Omega$ to $1Tera\Omega$.
- Resistance Tolerance K(±10%), M(±20%).
- Rated Wattage from 200W to 800W.

Applications:

- X-ray/imaging equipment,
- EMI/lightning supression, Energy research,
- Pulse modulators, Radar Pulse-forming networks,
- Impulse voltage generators, Arc furnace damping,
- Capacitor crowbar circuits, High voltage snubber circuits.

Token Electronics RI85 series has been developed to provide design engineers with high quality, high power, and high voltage dividers for use in sophisticated system.

The RI85 resistors use Token's proprietary thick film metal glaze resistive element and Serpentine Pattern Design which provides ideal cost efficient, stability, high power and high voltage characteristics for a wide range of measurement, voltage divider circuits, and control functions in high voltage power electronics applications.



Token RI85 Voltage Power Resistors are able to absorb large amounts of energy at high voltage while remaining non-inductive and heavy load characteristics. RI85 Resistors conform to the RoHS directives and Lead-free. Customed design, low TCR, resistance values, and tighter tolerances are available on request.

The RI85 non-inductive metal glazed resistors are manufactured on proceeding of tube designed with tab terminal, thick-film printing, firing and laser trimming.

By utilizing specific ceramic core materials with optimum processing, Token are able to control, very tightly in manufacturing, the important ultra-stable performance parameters TCR less than 100 ppm/°C. Voltage handles up to 100 KV and Wattage available 200W to 800W. This unique process is also offered in specific resistance values in a wide variety of sizes and terminations. The extraordinary operating stability of the Type RI85 resistors will improve the performance of your high voltage system.

The RI85 Power Voltage Series is RoHS compliant and lead free. For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact us, or link to Token official website "High Voltage Resistors" to get more information.

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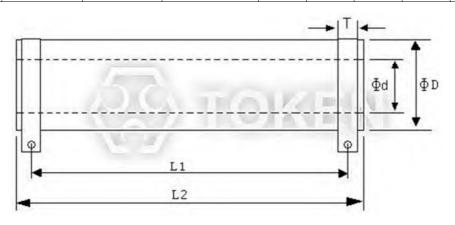
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Dimensions & Specification

Dimensions & Specification (RI85) (Unit: mm)

Туре	Power Rating	Resistance Value (Ω)	Resistance Tolerance	Temperature Coefficient (PPM/°C)	ΦD±2	Dimens Φd±2	ions (Un L1±5	it: mm)	T±1	Max working voltage
RI85	200W	100K~100G		≤100	28	15	185	200	10.5	50KV
RI85	500W	100K~500G	10% (K) 20% (M)	≤100	34	20	205	220	15	50KV
RI85	800W	100K~1T	20 / (111)	≤100	55	40	205	220	15	100KV



Tubular High Voltage Ceramic Resistors (RI85) Dimensions

• Remark: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV = square root (power rating × resistance value) or Max Working Voltage listed above, whichever less.

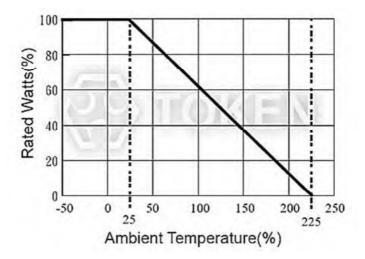
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Derating Curve

Power Derating Curve (RI85)



(RI85) Power Derating Curve

Performance Specifications

Performance Specifications (RI85)

Test Item	Test Methods	Characteristics
Moisture resistance	MIL Std. 202, method 106 (IEC68-2-3)	ΔR/R≤±0.1% typ., 0.25% Max.
Insulation resistance	500V 25°C 75% relative humidity	10GΩ Min.
Dielectric strength	25°C 75% relative humidity	1000V Min.
Overload	1.5×Pnom. 5 sec (do not exceed max. voltage)	ΔR/R≤±0.1% typ., 0.25% Max.
Thermal shock	MIL Std. 202, method 107 Cond. C (IEC68-2-14)	ΔR/R≤±0.1% typ., 0.2% Max.
Load life	1000h at rated power (IEC115-1)	ΔR/R≤±0.1% typ., 0.25% Max.

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Advance Technique

The Advantages of Non-Inductance & Serpentine Pattern - (RI85)

Non-Inductive Performance:

- RI85 Non-Inductive Design which uses a serpentine resistive pattern that offers for zigzagging lines to carry current in opposite directions, thereby achieving maximum neutralization of flux fields over the entire length of the resistor.
- This efficient non-inductive construction without derating of any performance advantages is ideal for applications where high frequency is required.



Serpentine Pattern Screen Printing Design:

- The RI85 High Voltage Power Resistor combines Token's Non-Inductive serpentine pattern, high thru-put screen printed silicone coating.
- The alignment of the gap in the serpentine resistor pattern with the gap in the coating pattern provides a complete encapsulation of the resistor element.
- The cap and lead assemblies are pressed onto the resistor core, finishing the resistor and providing rugged terminal attachment.

Order Codes

High Voltage Resistors (RI85)

RI85	200W	1M	K	
Product Type.	Rated Power.(W)	Resistance Value. (Ω)	Resistance Tolerance.	

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High Voltage Network Dividers (NTK)

Product Introduction

Token High Voltage Resistor Network Dividers can be customized to order.

Specifications:

- Resistance Range: $1K\Omega \sim 10G\Omega$.
- Resistance Tolerance: ±1% ~ ±30%.
- Thick film on Aluminum > 96% Al2O3.
- High Voltage Withstanding: Up to 30 ~ 50KV.
- Low VCR: 1ppm / 5ppm / 10ppm upon request.
- Temperature Range: -55°C ~ +125°C (higher temp. upon request).
- Low TCR Available: 250 ppm/°C. (ppm/°C or tighter upon request).

Features:

- Flat style, Low Resistor Noise.
- Non Inductive Design.
- Divider Design upon Request.
- Pb-free Production: Meet RoHS.
- Different Coating Available: Glass / Epoxy resin / Silicon.
- Solderable Leads (Tin coated copper leads):
 Type Φ0.5 (Φ0.6 / Φ0.8 upon request).

RoHS-compliant resistor network, high-value high-voltage resistors and potential dividers in a wide variety of configurations are now available from Token Electronics as custom versions of its standard ranges of resistive products.

This advanced film resistor technology provides the performance characteristics required by the precision input signal circuits of both bench-type and laboratory digital instruments. In addition to requiring less board space, these



compact voltage network dividers deliver higher performance than selected discrete resistor sets and thin-film dividers.

Manufactured using advance thick-film technology from existing tooling ensures fast turnaround of samples prior to low to medium volume in-house production. These custom dividers are ideal for high performance voltage division applications in medical equipment, laboratory equipment, analytical instruments, etc. The custom high voltage network divider can be supplied in various packages and packaging materials including glass, epoxy resin, silicon options.

By applying this technology to the low-profile, single-in-line package configuration, the Type (NTK) Custom SIP Resistor Networks are available with a combination of features. Which include: Low TCR 250 ppm/ $^{\circ}$ C (100 ppm/ $^{\circ}$ C or tighter upon request), operating temperature range -55 $^{\circ}$ C ~ +125 $^{\circ}$ C (higher temperature upon request), flat style, non-inductive, low noise, and also custom divider design.

For complete information on quantity price and delivery, please contact our Sales Office, or link to Token official website "High Voltage Resistors" to get more information.



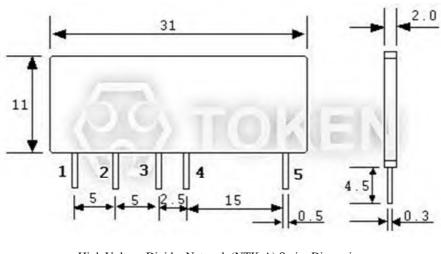




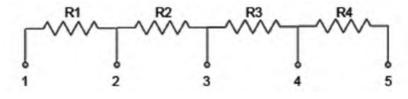
NTK-A Electrical Parameters

Electrical Parameters (NTK-A)

Туре	PIN	Resistance Value (Ω)		Resistance Tolerance	Pressure parameters	Rated Power (W)
NTK-A	1~2	R1	30M	K (±10%)	4KV Min.	0.6W Min.
	2~3	R2	30M	K (±10%)	4KV Min.	0.6W Min.
	3~4	R3	1M	J (±5%)	500V Min.	0.3W Min.
	4~5	R4	800M	K (±10%)	10KV Min.	1W Min.



High Voltage Divider Network (NTK-A) Series Dimensions



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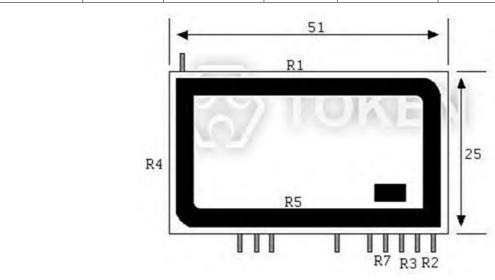
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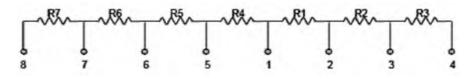
NTK-B Electrical Parameters

Electrical Parameters (NTK-B)

Туре	Serial Number	Resistance Value (Ω)	Rated Power	Resistance Tolerance	Temperature Coefficient	Operating Voltage
	R1	52M	5W			8500V
	R2	10K	-	-		-
	R3	10K	-			-
NTK-B	R4	16M2	4W	±5%	±250PPM/℃	4200V
	R5	17M3	3W			4400V
	R6	3M3	1W			800V
	R7	8K	-			-



High Voltage Divider Network (NTK-B) Series Dimensions



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Thick Film Planar Dividers, High Voltage Resistors (HI83)

▶ Product Introduction

Token electronic printing technology to achieve a superior precision, thick film planar high voltage dividers.

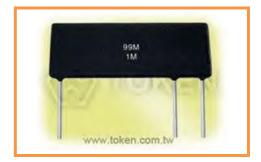
Features:

- High precision, Non-Inductance design.
- High voltage, Wide range of resistance.
- Custom design services. RoHS compliant.

Applications:

- Pulse Modulator, Radar Pulse Forming Network.
- X-ray/Imaging Equipment, and EMI lightning suppression.
- Capacitor Arc Suppression Circuit, High Voltage Buffer Circuit.
- Impulse Voltage Generator. Electric Arc Furnace Damping, Energy Research.

Through-hole (HI83) thick film planar divider, high voltage resistor series is a new generation of Token Electronic Technology Co., Ltd. Taking advantage of high-quality ruthenium oxide resistance material to 96% alumina planar ceramic matrix, dividers (HI83) features good thermal conductivity, small size, and high reliability. Custom dividers available with leadwire terminals or with leadless conductive pads.



The planar thick film divider resistor (HI83) provides stable performance over a wide range of resistance values with a voltage rating up to 35KV. The maximum resistance ratio is 1000: 1 (ratio greater than 1000: 1, such as 2000: 1, 4000: 1, and 5000: 1 is available on request) with a minimum resistance ratio of 40: 1.

Low temperature coefficient can be used for high stability circuit applications. Space-saving planar packages provide an alternative to traditional high-voltage resistors. (HI83) is mainly used in precision instruments, drive circuits, power supplies, transformers, high voltage power equipment, and any need to operate in high voltage electrical appliances and other fields.

The main structure of the planar thick film voltage divider (HI83): The terminal connecting conductor and the ruthenium oxide resistive material were printed on the surface of the 96% alumina substrate in a non-inductive pattern. Then apply the screen printing protection, after connect the terminals. Phosphor bronze solder is welded to the lead frame terminal and is immersed in SnAgCu to meet the following IEC weldability requirements.

Thick film (HI83) voltage dividers are RoHS compliant and 100% lead free. For conventional parameters, specifications outside the parameters, or technical requirements, please contact Token, or link to Token official website "High Voltage Resistors" to get more information.





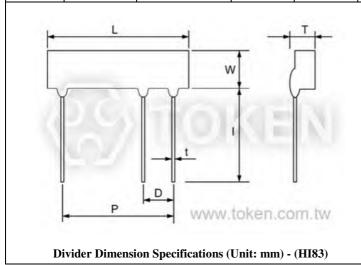
General Specifications

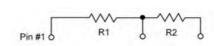
Composition Structure (HI83)



Dimension Specifications (Unit: mm) (HI83)

Part Number	Power Rating (W)	Max. Working Voltage (KV)	L±0.5 mm	W ±0.5 mm	P±1 mm	D ±0.5 mm	I ±1 mm	T ±0.5 mm	t ±0.05 mm
HI83-04	1/4W	10	25	5	22.6	4	20	2	0.6
HI83-02	1/2W	15	35	5	32	5	20	2	0.6
HI83-10	1W	15	38	8	27	6	20	2	0.6
HI83-20	2W	20	45	10	42	6	20	2	0.6
HI83-30	3W	25	60	10	59	8	40	3.5	1
HI83-50	5W	30	80	20	76.5	10	40	3.5	1





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► Electrical Characteristics

Technical Characteristics - (HI83)

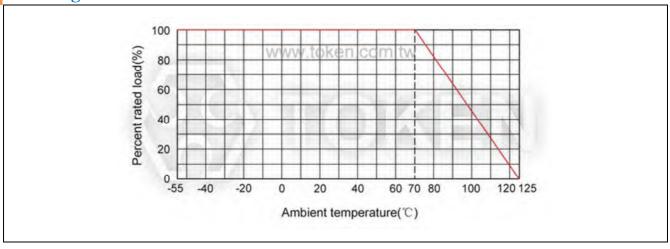
` /						
Part Number	HI83-04	HI83-02	HI83-10	HI83-20	HI83-30	HI83-50
Power rating at 70°C (W)	1/4W	1/2W	1W	2W	3W	5W
Limiting element voltage in air dc or ac pk (KV)	6KV	10KV	15KV	15KV	20KV	25KV
Resistance value (Ω)	10K-1G	50K-1G	100K-1G	100K-1G	100K-1G	100K-1G
Resistance tolerance (%)	1,5					
Ratio tolerance (%)	0.25, 0.5, 1					
TCR (20°C to 70°C) (ppm/°C)			50,	100		
Tracking TCR (20°C to 70°C) (ppm/°C)			25,	, 50		
Standard values		E24 p	referred for	(R1 + R2) a	nd R2	
Ambient temperature range (°C)	-55 to +125					
Insulation resistance at 500V (Ω)	>10G					
Dielectric strength of insulation (V)		•	>10	000		

▶ Environmental Characteristics

Environmental characteristics - (HI83)

Test Items	Condition	Spec.
Resistance Temp. Coeff.	-55°C ~125°C	±200 ~ ±300 ppm/°C
Overload	1.5 times of rated voltage, 15 min (do not exceed max. voltage)	$\Delta R \le \pm (\ 1\% R + 0.05\Omega\)$
Load Life	96 hours at rated power	$\Delta R \le \pm (1\%R + 0.1\%\Omega)$

Derating Curve



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Serpentine Pattern

Advance Technique of Non-Inductive & Serpentine Pattern (HI83)

Non-Inductive Performance:

- HI83 Non-Inductive Design which uses a serpentine resistive pattern that offers for zigzagging lines to carry current in opposite directions, thereby achieving maximum neutralization of flux fields over the entire length of the resistor.
- This efficient non-inductive construction without derating of any performance advantages is ideal for applications where high frequency is required.



Serpentine Pattern Screen Printing Design:

- Type High Voltage HI83 Precision Resistors combine Token's Non-Inductive serpentine pattern, high thru-put screen printed silicone coating.
- The alignment of the gap in the serpentine resistor pattern with the gap in the coating pattern provides a complete encapsulation of the resistor element.
- The cap and lead assemblies are pressed onto the resistor core, finishing the resistor and providing rugged terminal attachment.

Application Notes

High Voltage Divider Application Notes (HI83)

- Due to the high voltage that may occur between the terminals and any adjacent metal parts, the voltage divider should be installed at a sufficient distance from other conductors.
- For some ultra-high voltage applications, it is necessary to immerse the component in oil or SF6 gas or place it in a void-free silicone compound to reduce surface tracking or corona. The printed protection is right for these applications.
- The planar voltage divider consists of high value R1 and low value R2. The voltage division ratio of the divider is specified by Ratio R2: (R1 + R2).

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Order Codes

Order Codes (HI83)

Example:

HI83-20 for a voltage ratio of 1:1000, with R1 = 99.9 megohms and R2 = 100 kilohms (total R1 + R2 = 100 megohms) at 50ppm/°C absolute and 25ppm/°C tracking TCR, 1% absolute and 0.5% ratio tolerance.

HI83		20	C2C3		1	100M		100K		FD	
Part		Size	Т	「CR (ppm/°C)	$R1 + R2(\Omega)$		R2 (Ω)		Resistance Tolerance		
Number	04	1/4W	C1C2	100ppm absolute and	100M	99MΩ +	1M	1ΜΩ	(%)		
HI83	02	1/2W	CICZ	50ppm tracking	100111	1MΩ	100K	100ΚΩ	JF	5% absolute and 1% ratio	
	10	1W	C1C3	100ppm absolute and 25ppm tracking	100M	99.9MΩ + 100KΩ	1M5	1.5ΜΩ		1% fatto 1% absolute and	
	20	2W	1	50ppm absolute and		148.5MΩ +			FD	0.5% ratio	
	30	3W	C2C3	25ppm tracking	150M	1.5ΜΩ			FC	1% absolute and	
	50	5W				"				0.25% ratio	

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Precision High-Megohm High-Value Chip Resistors (HM)

Product Introduction

Token (HM) non-magnetic chip resistor providing high resistance value and high-temperature application performance.

Features:

- Non-magnetic.
- Non-standard values available.
- Low temperature and voltage dependency.
- Contact areas PtAg for glueing and soldering.
- Untrimmed for higher working voltage up to 6000V.

Packaging:

- Halogen-free, compiant to RoHS directive 2002/95/EC.
- Bilk in plastic bags or tubes MOQ 100 pieces.
- Blister tape IEC60286-3 MOQ 1000 pieces.
 Reel diameter 180mm or 330mm.

Token non-magnetic SMD resistor (HM) series, applied to the field of medical high magnetic fields, such as electronic circuits located in magnetic resonance (MRI) and computed tomography (CT), or in the extreme environment of oil and gas industries, such as downhole instruments for oil wells, or flight control in aerospace applications.

(HM) SMD Resistor series its junction area does not contain nickel, they are made of metal alloy PtAg, can be used as thick film slurry, suitable for roll coating or impregnation process to the packaging chipset parts area. The standard SMD soldering process can also be used in the bonding process of silver conductive epoxy resins. The

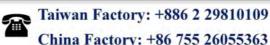


bonding technology of conductive epoxy resin is mainly used in the case of welding technology can not be applied, such as the temperature sensitive component which is affected by the high welding temperature, or the semiconductor without cladding on the same board. PtAg terminals are suitable for high temperature welding applications, which can be higher than the 155° C of typical soldering.

Similarly, (HM) chip resistors do not contain organic materials, no tin or tin lead layer, and resistance and conductive layer at 850° C high-temperature sintering, so the resistor chip will not have a substantial change, and has a stable electrical characteristics. The terminal material also affects the VCR (the voltage coefficient of the resistor), which is an important characteristic of the high-voltage resistor, and lower VCR is also designed for the Token of the non-magnetic SMD resistor.

Token non-magnetic thick flim chip resistor (HM) series, it consists of two main categories: (HMM) Precision High Value Chips and (HMS) Conventional Precision Megohm Chips. Sizes are 0402, 0603, 0805, 1206, 1210, 2512, and 4020 available. Resistance range from $100 \mathrm{K}\Omega$ to the highest value $10 \mathrm{T}\Omega$. Operating voltage can reach 6000V. Precision tolerance has 0.25%/0.5%/1%/2%/5%/10%/20%/30% alternative. The temperature coefficient is low to $25 \mathrm{ppm}/^{\circ}\mathrm{C}$. The voltage factor VCR can be specified within the range, from low to $25 \mathrm{ppm}/\mathrm{v}$.

(HM) chips compliant with RoHS and lead-free standards. Provide more competitive prices and fast delivery services. For technical requirements and special applications outside the specification, please contact the business representative of the Token Electronics, or link to Token official website "High Voltage Resistors" to get more information.



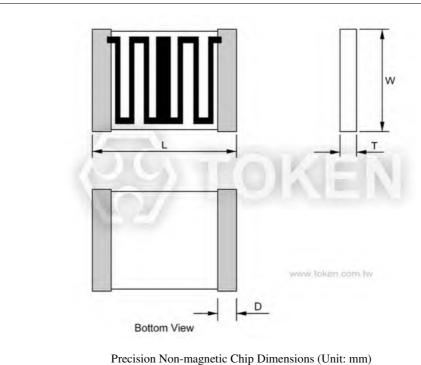
Dimensions

Precision Non-magnetic Chip Dimensions (Unit: mm)

	0 1	•							
(HMM) Precision High Value Chip Resistors									
Part Number	L (mm)	W (mm)	T (mm)	D (mm)					
HMM-0805	2.00+0.15/-0.05	1.25+0.15/-0.05	0.40+0.15/-0.05	0.30+0.20/-0.10					
HMM-1206	3.20+0.15/-0.05	1.50+0.20/-0.05	0.40+0.15/-0.05	0.30+0.20/-0.10					
HMM-1210	3.20+0.15/-0.05	2.50+0.20/-0.05	0.50+0.15/-0.05	$0.80^{\pm0.20}$					
HMM-2010	5.10+0.15/-0.05	2.50+0.20/-0.05	0.60+0.20/-0.10	$1.20^{\pm0.20}$					
HMM-2512	6.30+0.15/-0.05	3.50 ^{+0.20/-0.05}	0.60+0.15/-0.05	$0.90^{\pm0.20}$					
HMM-4020	10.20+0.20/-0.05	5.10+0.20/-0.05	0.60+0.20/-0.10	$0.90^{\pm0.20}$					
Note: L = Length,	H = Width, T = Thickn	ess, D = width of wrap	around •						

(HMS) Conventional Precision Megohm Chip Resistors									
Part Number	L (mm)								
HMS-0402	1.04 ^{±0.05}	$0.50^{\pm0.05}$	0.30 ^{±0.05}	0.10+0.10/-0.05					
HMS-0603	1.50+0.15/-0.05	0.80 ^{+0.15/-0.05}	0.40+0.15/-0.05	0.20+0.20/-0.10					
HMS-0805	2.00+0.15/-0.05	1.25 ^{+0.15/-0.05}	0.40+0.15/-0.05	0.30+0.20/-0.10					
HMS-1206	3.20+0.15/-0.05	1.50+0.20/-0.05	0.40+0.15/-0.05	0.30+0.20/-0.10					
HMS-1210	3.20+0.15/-0.05	2.50 ^{+0.20/-0.05}	0.50 ^{+0.15/-0.05}	$0.80^{\pm0.20}$					
HMS-2512	6.30+0.15/-0.05	3.50 ^{+0.20/-0.05}	0.60+0.15/-0.05	$0.90^{\pm0.20}$					
HMS-4020	10.20+0.15/-0.05	5.10 ^{+0.20/-0.05}	0.60+0.15/-0.05	$0.90^{\pm0.20}$					

Note: L = Length, H = Width, T = Thickness, D = width of wrap around •



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HMM Electrical characteristics

Technical Characteristics - (HMM)

Part	Power Rating	Working	Voltage (V)	Resistance	Tolerance	TCR ⁽²⁾ (ppm /°C)	VCR ⁽³⁾
Number	P ₇₀ (mW)	trimmed	untrimmed	Range (Ω)	(%)	TCK (ppm/C)	(ppm/V)
				100K - 100M	0.5/1/5/10	TC25/50/100	<50ppm/V
				>100M - 1G	2/5/10/20	TC50/100/250	<250ppm/V
II) #3 # 000 #	105	200	600	>1G - 10G	5/10/20	TC100/250	<500ppm/V
HMM-0805	125	200	600	>10G - 100G	10/20/30	TC1000/2000	<1000ppm/V
				>100G - 1T	-	-	-
				>1T - 10T	-	-	-
				100K - 100M	0.5/1/2/5/10	TC25/50/100	<50ppm/V
				>100M - 1G	2/5/10/20	TC50/100/250	<100ppm/V
HMM-1206	250	600	1000	>1G - 10G	5/10/20	TC100/250	<250ppm/V
	250	600	1000	>10G - 100G	10/20/30	TC500/1000	<1000ppm/V
				>100G - 1T	10/20/30	TC1000/2000	<2000ppm/V
				>1T - 10T	-	-	-
				100K - 100M	0.5/1/2/5/10	TC25/50/100	<25ppm/V
			1200	>100M - 1G	1/2/5/10/20	TC25/50/100	<50ppm/V
HMM-1210 3	250	1000		>1G - 10G 2/5/1		TC50/100	<100ppm/V
	350			>10G - 100G	5/10/20/30	TC500/1000	<500ppm/V
				>100G - 1T	5/10/20/30	TC500/1000	<1000ppm/V
				>1T - 10T	-	-	-
			2000	100K - 100M	0.5/1/2/5/10	TC25/50/100	<25ppm/V
				>100M - 1G	1/2/5/10/20	TC25/50/100	<50ppm/V
HMAN 2010	500	1500		>1G - 10G	2/5/10/20	TC50/100	<100ppm/V
HMM-2010	300	1500	2000	>10G - 100G	5/10/20/30	TC250/500	<500ppm/V
				>100G - 1T	5/10/20/30	TC500/1000	<1000ppm/V
				>1T - 10T	-	-	<50ppm/V <250ppm/V <500ppm/V <500ppm/V <1000ppm/V <50ppm/V <100ppm/V <250ppm/V <1000ppm/V <2000ppm/V - <25ppm/V <50ppm/V <100ppm/V <500ppm/V <1000ppm/V <500ppm/V <1000ppm/V <500ppm/V <500ppm/V <500ppm/V <500ppm/V <500ppm/V <500ppm/V
				100K - 100M	0.5/1/2/5/10	TC25/50/100	<10ppm/V
				>100M - 1G	1/2/5/10/20	TC25/50/100	<25ppm/V
HMAN 2512	1000(1)	2000	3000	>1G - 10G	2/5/10/20	TC500/100	<100ppm/V
HMM-2512	1000	2000	3000	>10G - 100G	5/10/20/30	TC250/500	<250ppm/V
				>100G - 1T	5/10/20/30	TC500/1000	<500ppm/V
				>1T - 10T	10/20/30	TCR VCR	on request
				100K - 100M	0.25//10	TC25/50/100	<10ppm/V
				>100M - 1G	0.5//20	TC25/50/100	<100ppm/V <250ppm/V <1000ppm/V <2000ppm/V <2000ppm/V <2000ppm/V <50ppm/V <100ppm/V <1000ppm/V <1000ppm/V <50ppm/V <100ppm/V <100ppm/V <50ppm/V <100ppm/V <50ppm/V <100ppm/V <100ppm/V <10ppm/V <10ppm/V <25ppm/V <10ppm/V <10ppm/V <25ppm/V <10ppm/V <10ppm/V <25ppm/V <10ppm/V <10ppm/V <250ppm/V <10ppm/V <10ppm/V <250ppm/V <10ppm/V
HMM 4020	1500 ⁽¹⁾	4000	6000	>1G - 10G	1/2/5/10/20	TC25/50/100	<25ppm/V
HMM-4020	1300	4000	6000	>10G - 100G	2/5/10/20/30	TC250/500	<100ppm/V
				>100G - 1T	5/10/20/30	TC500/1000	<250ppm/V
				>1T - 10T	10/20/30	TCR VCR	on request

- Note:

 (1) At continuous power dissipation the dimensions of solder-pads have to secure sufficient heat-conduction.

 (2) TCR 25/50: Temperature range +25°C ~ +85°C; (3) VCR: Typical values.
- Lower values of tolerance, TCR and VCR on request and agreement.

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Environmental Characteristic

Temperature range	-55°C ~+155°C				
Climatic category acc. to IEC 60068	55/155/56				
Max. soldering temperature acc. IEC60068 T2-20, Ta Meth.1 ⁽⁴⁾	235℃ 5s				
Max. soldering temperature acc. IEC60068 T2-20, Tb Meth.1A	260°C 10s				
Long term stability	<1G	<10G	≥10G		
Storage 125°C/1000h	<0.5%	<1%	<2%		
Load life 70°C/1000h	<0.25%	<0.5%	<1%		

- Note:

 (4) Up to 6 months after shipment resp, at storage in Nitrogen.
- Data not specified according CECC 40401-802.

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HMS Electrical characteristics

Technical Characteristics - (HMS)

Part	Power Rating	Working	Voltage (V)	Resistance	Tolerance	TCR ⁽²⁾ (ppm /°C)	VCR ⁽³⁾
Number	P ₇₀ (mW)	trimmed	untrimmed	Range (Ω)	(%)	TCK (ppin/C)	(ppm/V)
				1M - 100M	5/10/20	TC100/250	<500ppm/V
				>100M - 500M	5/10/20	TC250/500	<1000ppm/V
				>500M - 1G	5/10/20	TC250/500	<1000ppm/V
HMS-0402	50	30	90	>1G - 10G	10/20/30	TC1000/2000	<2000ppm/V
				>10G - 100G	-	-	-
				>10G 100G	_	_	_
				1M - 100M	1/5/10/20	TC100/250	<250ppm/V
				>100M - 500M	2/5/10/20	TC100/250	<250ppm/V
				>500M - 1G	5/10/20	TC250/500	<500ppm/V
HMS-0603	75	75	200	>1G - 10G	5/10/20/30	TC500/1000	<2000ppm/V
				>10G - 100G	10/20/30	TC1000/2000	<5000ppm/V
				>100 1000 >100G - 1T	-	-	-
				1M - 100M	1/5/10/20	TC50/100	<100ppm/V
				>100M - 500M	2/5/10/20	TC100/250	<250ppm/V
				>500M - 1G	5/10/20	TC250/500	<250ppm/V
HMS-0805	125	100	300	>1G - 10G	5/10/20	TC500/1000	<1000ppm/V
				>10G - 100G	10/20/30	TC1000/2000	<2000ppm/V
				>100G - 1T	10/20/30	TC3000	<5000ppm/V
				1M - 100M	1/5/10/20	TC25/50/100	<100ppm/V
				>100M - 500M	2/5/10/20	TC50/100/250	<100ppm/V
	2.50	200	600	>500M - 1G	5/10/20	TC100/250	<250ppm/V
HMS-1206	250		600	>1G - 10G	5/10/20	TC500/1000	<1000ppm/V
				>10G - 100G	10/20/30	TC1000/2000	<2000ppm/V
				>100G - 1T	10/20/30	TC3000	<5000ppm/V
				1M - 100M	1/5/10/20	TC25/50/100	<50ppm/V
				>100M - 500M	2/5/10/20	TC50/100/250	<100ppm/V
TTN FC 1010	250	200	000	>500M - 1G	5/10/20	TC100/250	<100ppm/V
HMS-1210	350	300	900	>1G - 10G	5/10/20	TC250/500	<500ppm/V
				>10G - 100G	5/10/20	TC500/1000	<1000ppm/V
				>100G - 1T	5/10/20/30	TC1000/2000	<2000ppm/V
				1M - 100M	1//20	TC25/50/100	<10ppm/V
				>100M - 500M	1/5/10/20	TC25/50/100	<25ppm/V
TIME 2512	1000(1)	1000	2000	>500M - 1G	1/5/10/20	TC100/250	<25ppm/V
HMS-2512	1000	1000	2000	>1G - 10G	2/5/10/20	TC250/500	<100ppm/V
				>10G - 100G	5/10/20	TC250/500	<250ppm/V
				>100G - 1T	5/10/20	TC500/1000	<500ppm/V
				1M - 100M	1//10	TC25/50/100	<5ppm/V
				>100M - 500M	0.5/1/5/10/20	TC25/50/100	<10ppm/V
TIME 4020	1500 ⁽¹⁾	4000	6000	>500M - 1G	1/5/10/20	TC25/50/100	<10ppm/V
HMS-4020	1300	4000	0000	>1G - 10G	2/5/10/20	TC50/100	<25ppm/V
				>10G - 100G	5/10/20/30	TC100/250	<100ppm/V
				>100G - 1T	5/10/20/30	TC250/500	<250ppm/V

- Note:

 (1) At continuous power dissipation the dimensions of solder-pads have to secure sufficient heat-conduction.

 (2) TCR 25/50: Temperature range +25°C ~ +85°C; (3) VCR mesdured between 10V and 100V.
- Lower values of tolerance, TCR and VCR on request and agreement.

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Environmental Characteristic

Temperature range	-55°C ~+155°C				
Climatic category acc. to IEC 60068	55/155/56				
Max. soldering temperature acc. IEC60068 T2-20, Ta Meth.1 ⁽⁴⁾	235°C 5s				
Max. soldering temperature acc. IEC60068 T2-20, Tb Meth.1A	260℃ 10s				
Long term stability	<1G	<10G	≥10G		
Storage 125°C/1000h	<1%	<2%	<5%		
Load life 70°C/1000h	<0.5%	<1%	<2%		

- Note:

 (4) Up to 6 months after shipment resp, at storage in Nitrogen.

 Data not specified according CECC 40401-802.

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Order Codes

Order Codes (HMM) - Precision High Value Chip Resistors

HMM	0805		1G			M	E		
Part Number	Rated Power (W)		Resistance Value (Ω)		Resist	Resistance Tolerance		TCR (ppm/°C)	
НММ	0805	125mW	1M1	1.1ΜΩ		(%)	С	±25ppm/°C	
	1206	250mW	110M	110MΩ	С	±0.25%	D	±50ppm/°C	
	1210	350mW	1G5	1.5GΩ	D	±0.5%	Е	±100ppm/°C	
	2010	500mW	10G	10GΩ	F	±1%	L	**	
	2512	1000mW	1T	1ΤΩ	G	±2%		±250ppm/°C	
	4020	1500mW	10T	10ΤΩ	J	±5%	I	±500ppm/°C	
	1020 13001111 10122				K	±10%	R	±1000ppm/°C	
						±20%	S	±2000ppm/°C	
					N	±30%			

Order Codes (HMS) - Conventional Precision Megohm Chip Resistors

•									
HMS	0402		1G		M		E		
Part Number	Rated Power (W)		Resistance Value (Ω)		Resist	Resistance Tolerance		TCR (ppm/°C)	
HMS	0402	50mW	1M1	$1.1 \mathrm{M}\Omega$		(%)	С	±25ppm/°C	
	0603	75mW	110M	110MΩ	D	±0.5%	D	±50ppm/°C	
	0805	125mW	1G5	1.5GΩ	F	±1%	E		
	1206	250mW	10G	10GΩ	G	±2%		±100ppm/°C	
	1210	350mW	1T	1ΤΩ	J	±5%	L	±250ppm/°C	
	2512	1000mW	11	1122	K	±10%	I	±500ppm/°C	
					M	±20%	R	±1000ppm/°C	
	4020	1500mW			N	±30%	S	±2000ppm/°C	
					11	±30%		**	
							T	±3000ppm/°C	

• Note: If no requirements for TCR, measuring voltage and taping are given, the standard value (highest value in table) will be supplied, measuring voltage of 10V is used and packaging is bulk.

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Ultra-Precision High-Power High-Voltage Resistors (HI80)

▶ Product Introduction

New ruthenium material, extended ultra-precision high-power high-voltage resistors (HI80) breakthrough 300W, precision narrowed to 0.1%.

Features:

- Thick film sensorless design.
- Wide range of resistance.
- Bottom temperature coefficient and high precision.
- Resistance to humidity, heat and electricity.
- Long term performance, stable and reliable.

Applications:

- Impulse voltage generators,
- Arc furnace damping, Energy research,
- Pulse modulators, Radar Pulse-forming networks,
- Capacitor crowbar circuits, High voltage snubber circuits,
- X-ray/imaging equipment, and EMI/lightning supression.

Token electronic ultra-precision high-power high-voltage resistor (HI80) family series take advantage of new ultra-fine ruthenium material, 95% aluminum oxide ceramic rods, and thick film non-inductive Serpentine Pattern Design. Precision can be narrowed to ±0.1%, and power breakthrough 300W. (HI80) featuring heat-resistant, humidity-resistant, resisting electrical pulse, and stable and reliable long-term performance, is specifically designed for general purpose industrial high voltage system applications.



(HI80) family of high-voltage resistors includes conventional high-voltage resistors (HI80D), conventional miniaturized high-voltage resistors (HI80DS), high-power high-voltage resistors (HI80P), and ultra-precision high-voltage resistors (HI80T).

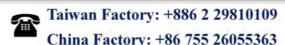
Conventional high voltage resistors (HI80D) have a wide resistance range of $200\Omega \sim 10G\Omega$, rated power 2.5W ~ 20 W, accuracy tolerance F ($\pm 1\%$), J ($\pm 5\%$), K ($\pm 10\%$), the lowest temperature coefficient down to 50ppm on request, and the standard temperature coefficient of 100ppm.

(HI80DS) All-film conventional miniature high-voltage resistor relative to (hi80d), with small size, higher power 3W ~ 30W, withstand higher voltage, and none-inductance. The temperature coefficient of the lowest can reach 50ppm (25°C ~105°C), the standard temperature coefficient of 100ppm. Precision Tolerances F (\pm 1%), J (\pm 5%), K (\pm 10%).

High power high voltage resistors (HI80P) have high rated power 20W ~ 300W, resistance range 1Ω ~ $1G\Omega$, precision tolerance D (± 0.5%), F (± 1%), J (± 5%), K (± 10%), The temperature coefficient of up to 25ppm (on request), the standard temperature coefficient of 50ppm.

Ultra-precision high-voltage resistor (HI80T) characters 15ppm temperature coefficient, the standard temperature coefficient is 25ppm, the precision tolerance has B (\pm 0.1%), D (\pm 0.5%), F (\pm 1%), the resistance range $1\Omega \sim 500 M\Omega$, and the rated power 0.8W \sim 6W to choose from.

Token (HI80) Voltage Resistor series is able to absorb large amounts of energy at high voltage while remaining non-inductive and heavy load characteristics. The HI80 conforms to the RoHS directives and Lead-free. Customed design, and tighter tolerances are available on request. For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact our sales for more information or link to Token official website "High Voltage Resistors" to get more information.





HI80D Spec.

Conventional High Voltage Resistor Construction (HI80D)



Specifications & Painted Dimensions (Unit: mm) (HI80D)

	Rated power (W)	Max.	Resistance range (Ω)		Dimensions (mm)				
Part Number	Ambient temperature (75°C)	Oper. Volt (KV)	Min.	Max.	L ±0.5mm	E ±3mm	D ±0.5mm	d ±0.1mm	
HI80D-15	0.5	3.0	200	1G	15	30	5.0	0.8	
HI80D-20	2.5	4.8	200	1G	20	28	8.0	1.0	
HI80D-26	3.7	6.4	250	1G	27	28	8.0	1.0	
HI80D-32	4.5	8.0	300	1.5G	33	28	8.0	1.0	
HI80D-39	5.2	12.8	400	1.5G	39	28	8.0	1.0	
HI80D-52	7.5	16	500	2.5G	52	28	8.0	1.0	
HI80D-78	11	24	900	4G	78	28	8.0	1.0	
HI80D-103	12	32	1K2	6G	103	28	8.0	1.0	
HI80D-124	15	40	1K5	8G	124	28	8.0	1.0	
HI80D-154	20	45	2K	10G	154	28	8.0	1.0	



Conventional High Voltage Resistor Painted Dimensions (Unit: mm) - (HI80D)

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HI80DS Spec.

Conventional Miniature High Voltage Resistor Construction (HI80DS)



Conventional Miniature Specifications & Painted Dimensions (Unit: mm) (HI80DS)

	Rated power (W)	Max.	Resistance range (Ω)		Dimensions (mm)				
Part Number	Ambient temperature (75°C)	Oper. Volt (KV)	Min.	Max.	L ±0.5mm	E ±3mm	D ±0.5mm	d ±0.1mm	
HI80DS-20	3	4.8	200	1G	20.2	30	8.2	1.0	
HI80DS-26	5	6.4	250	1G	26.9	30	8.2	1.0	
HI80DS-32	7	8.0	300	1.5G	33.0	30	8.2	1.0	
HI80DS-39	9	12.8	400	1.5G	39.5	30	8.2	1.0	
HI80DS-52	10	16	500	2.5G	52.1	30	8.2	1.0	
HI80DS-78	15	24	900	4G	77.7	30	8.2	1.0	
HI80DS-103	20	32	1K2	6G	102.9	30	8.2	1.0	
HI80DS-124	25	40	1K5	8G	123.7	30	8.2	1.0	
HI80DS-154	30	45	2K	10G	153.7	30	8.2	1.0	



Conventional Miniature Specifications & Painted Dimensions (Unit: mm) - (HI80DS)

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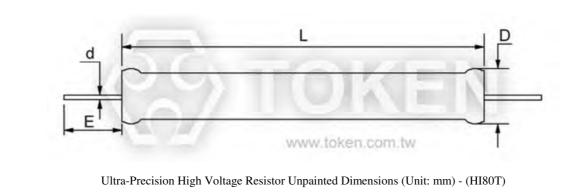
HI80T Spec.

Conventional High Voltage Resistor Construction (HI80D)



Ultra-Precision High Voltage Resistor Specifications (HI80T)

	O						
Part Number	Rated power (W)	Max. continuous Oper. Volt (KV)	Resistance range (Ω)	L ±0.5mm	E ±3mm	D ±0.5mm	d ±0.1mm
HI80T-20	0.8	3	1 ~ 500M	20	30	8	1
HI80T-26	1.0	4	1 ~ 500M	27	30	8	1
HI80T-32	1.2	5	1 ~ 500M	33	30	8	1
HI80T-39	1.5	6	1 ~ 500M	39	30	8	1
HI80T-52	2	10	1 ~ 500M	52	30	8	1
HI80T-78	3	15	1 ~ 500M	78	30	8	1
HI80T-103	4	20	1 ~ 500M	103	30	8	1
HI80T-124	5	25	1 ~ 500M	124	30	8	1
HI80T-154	6	30	1 ~ 500M	154	30	8	1



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HI80P Specifications

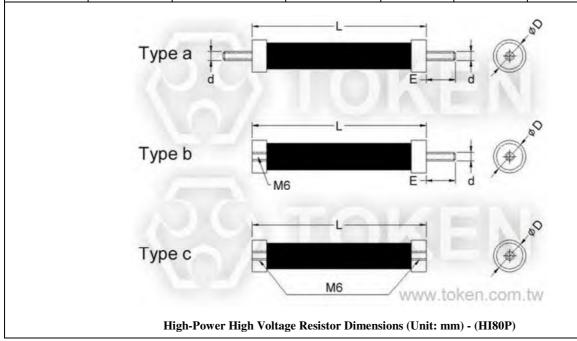
High-Power High Voltage Resistor Construction (Unit: mm) (HI80P)



Membrane Material (a)	Ruthenium Paste
Base Material (b)	95% Aluminum Oxide, Al ₂ O ₃
Encapsulating Material (c)	High Temperature Silicone Resin
Cap (d)	Nickel Plating Copper

High-Power High Voltage Resistor Specifications (Unit: mm) (HI80P)

Part Number	Rated power (W)	Max. continuous Oper. Volt (KV)	Resistance range (Ω)	L±1mm	E ±1mm	D ±0.5mm	d ±0.01mm
HI80P-20	20	30	1 ~ 1G	116	10	17	M6
HI80P-30	30	30	1 ~ 1G	116	10	19	M6
HI80P-50	50	30	1 ~ 1G	116	10	21	M6
HI80P-80	80	30	1 ~ 1G	130	10	28	M6
HI80P-100	100	35	1 ~ 1G	160	10	28	M6
HI80P-150	150	60	1 ~ 1G	210	10	28	M6
HI80P-200	200	60	1 ~ 1G	260	10	28	M6
HI80P-300	300	80	1 ~ 1G	310	10	33	M6



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▶ Environmental Characteristics

Technical Characteristics - (HI80)

Part Number	Resistance range (Ω)	Tolerance (%)	TCR @25°C (-55°C ~+105°C)	Insulation withstand voltage	Insulation resistance	Operating temp. range
HI80D	200 ~ 10G	±1% ~ ±10%	± 100 ppm/°C, (± 50 ppm/°C on request)		≥ 10GΩ	-55°C ~ +225°C
HI80DS	200 ~ 10G	±5% ~ ±10%	± 100 ppm/°C, (± 50 ppm/°C on request)	1000VDC		
HI80T	1 ~ 500M	±0.1% ~ ±1%	±25ppm/°C, (±15ppm/°C on request)	1000 V D C		
HI80P	1 ~ 1G	±0.5% ~ ±10%	±50ppm/°C, (±25ppm/°C on request)			

Environmental Characteristics - (HI80)

Inspection item	Inspection method	Performance requirement
Overload	5 times the rated power, but not more than 1.5 times the maximum continuous operating voltage, 5 seconds	$\Delta R \le \pm (0.2\% R + 0.01\Omega)$
Load life	1000 hours under rated power	$\Delta R \le \pm (0.5\% R + 0.01\Omega)$
Steady-state damp heat	40° C, RH $\geq 95\%$, 240h	$\Delta R \le \pm (0.4\% R + 0.01\Omega)$
Temperature shock	-65°C ~ 155°C, 5 cycle	$\Delta R \le \pm (0.2\% R + 0.01\Omega)$

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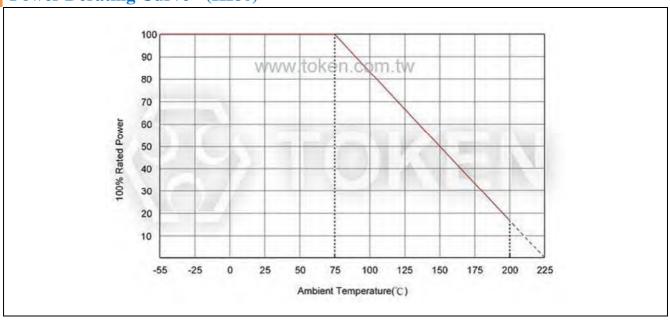
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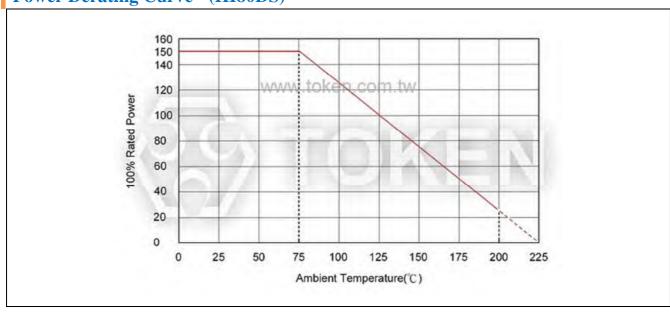


▶ Power Derating Curve

Power Derating Curve - (HI80)



Power Derating Curve - (HI80DS)



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Serpentine Pattern

Advance Technique of Non-Inductive & Serpentine Pattern (HI80)

Non-Inductive Performance:

- HI80 Non-Inductive Design which uses a serpentine resistive pattern that offers for zigzagging lines to carry current in opposite directions, thereby achieving maximum neutralization of flux fields over the entire length of the resistor.
- This efficient non-inductive construction without derating of any performance advantages is ideal for applications where high frequency is required.



Serpentine Pattern Screen Printing Design:

- Type High Voltage HI80 Precision Resistors combine Token's Non-Inductive serpentine pattern, high thru-put screen printed silicone coating.
- The alignment of the gap in the serpentine resistor pattern with the gap in the coating pattern provides a complete encapsulation of the resistor element.
- The cap and lead assemblies are pressed onto the resistor core, finishing the resistor and providing rugged terminal attachment.

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Order Codes

Order Codes (HI80D) Conventional High Voltage Resistor

HI80D	39			1G	F		
Part Number	Rated Power (W)		Resis	Resistance Value (Ω)		Resistance Tolerance (%)	
HI80D	20	2.5W	1K1	1.1ΚΩ	F	±1%	
	26	3.7W	110K	110ΚΩ	J	±5%	
	39	5.2W	1M1	1.1ΜΩ	K	±10%	
	103	12W	110M	110ΜΩ			
	154	20W	1G5	1.5GΩ			
			10G	10GΩ			

• Note: TCR 100ppm/°C, (±50ppm/°C on request).

Order Codes (HI80DS) Conventional Miniature high voltage resistors

•			0 0					
HI80DS		124		1G	F			
Part Number	Rated Power (W)		Resistance Value (Ω)		Resistance Tolerance (%)			
HI80DS	20	3W	1K1 1.1KΩ		J	±5%		
	32	7W	110K	110ΚΩ	K	±10%		
	78	15W	1M1	$1.1 \mathrm{M}\Omega$				
	103	20W	110M	110MΩ				
	154	30W	1G5	1.5GΩ				
			10G	$10G\Omega$				

• Note: TCR 100ppm/ $^{\circ}$ C, (\pm 50ppm/ $^{\circ}$ C on request).

Order Codes (HI80T) Ultra-Precision High Voltage Resistor

			0	8			
HI80T	32			500M	В		
Part Number	Rat	ted Power (W)	Resistance Value (Ω)		Resista	Resistance Tolerance (%)	
HI80T	20	0.8W	10	10 10Ω		±0.1%	
	32	1.2W	1K1	1.1ΚΩ	D	±0.5%	
	52	2W	110K	110KΩ	F	±1%	
	154	6W	1M1	1.1ΜΩ			
			500M	500MΩ			

• Note: TCR ±25ppm/°C, (±15ppm/°C on request).



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Order Codes (HI80P) High-Power High Voltage Resistor

HI80P	20		a		1G		F	
Part Number	Rate	d Power (W)	Туре	Resis	Resistance Value		Resistance	
HI80P	20	20W	a	(Ω)		Tolerance (%)		
	30	30W	b	10	10Ω	D	±0.5%	
	150	150W	С	1K1	1.1ΚΩ	F	±1%	
	300	300W		110K	110KΩ	J	±5%	
	200	20011		1M1	1.1ΜΩ	K	±10%	
				110M	110ΜΩ			
				10G	10GΩ			

• Note: TCR ± 50 ppm/°C, (± 25 ppm/°C on request).

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Ultra-Precision High Voltage Film Resistors (HI82)

Product Introduction

Up to $10T\Omega$, (HI82) sets a new standard for high value, ultra-stable precision high voltage resistors.

(HI82) Family Members:

- (HI82D) Precision High-Voltage High-Value Resistor series, resistance range from $1m\Omega$ to $10T\Omega$, precision tolerance from 30% to 0.25%, rated power has 1w/1.2w/3w selectable.
- (HI82H) Conventional Precision High-Voltage High Resistance Resistor series, various precision tolerance 1%/2%/5%/10%/20%/30%/50% available, four kinds of rated power 0.5 w/0.7/1 w/2 w selectable, resistance from $1\text{M}\Omega$ to $1\text{T}\Omega$.
- (HI82T) High Power Voltage Resistor series, maximum operating voltage up to 35KV, 30W high rated power to 0.125W, resistance range from 1Ω to $500M\Omega$, tolerance range 0.5% to 5%.

Features:

- High voltage thick film precision technology resistor.
- Resistance up to $10T\Omega$. Low TCR, low VCR.
- Radial leads, variable lead spacing by bending.
- Climatic protection by silicone coating

Applications:

- Impulse voltage generators,
- Arc furnace damping, Energy research,
- Pulse modulators, Radar Pulse-forming networks,
- Capacitor crowbar circuits, High voltage snubber circuits,

The high performance high-voltage applications require the use of high voltage resistors in applications with long-term stability and good temperature coefficient. Token Electronics has introduced ultra-stable high-precision HI82 high voltage resistors to meet these needs.

Token's unique precision full film and serpentine transfer pattern (serpentine patterns design), using a specifical high speed fine-line thick film dispensing system, developed a series of high voltage application resistor components with excellent performance. Especially in smaller sizes and higher resistance-value components.



Through the use of alloy ruthenium paste material, and 95% high aluminum planar ceramic chip, Token can control the manufacture of very precise precision and stabilize the performance parameters of important high-voltage operating temperature range. (HI82) thick film resistor combined with close tracking design, with low current noise, linear current voltage, low TCR, high temperature durability, wide resistance range, long-term stability, and low-cost advantages.

Token HI82 ultra-precision high-voltage resistors conform with RoHS and lead-free standards and provide more competitive prices and fast delivery service. For technical specifications and special applications, please contact your Token's sales representative, or link to Token official website "High Voltage Resistors" to get more information.

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Dimensions

Composition Structure (HI82)



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Ultra-precision high value voltage Resistor Dimensions (Unit: mm)

HI82D Ultra-precision high-voltage high-value resistor										
Part Number	per L ±1mm H ±1mm T ±0.5mm P ±2mm I ±3mm d ±0.1mm									
HI82D-1W	30.0	6.0	1.4	27.5	20	0.4				
HI82D-1BW	40.0	6.0	1.4	37.8	20	0.4				
HI82D-3W	50.0	12.5	1.4	47.8	20	0.4				

Note: L = Length, H = Width, T = Thickness, I = Length of steel wire, d = Wire diameter \circ

P = Standard lead spacing (Other spacing possible by bending) •

HI82H Conventional precision high-voltage high-resistance resistor										
Part Number	L ±1mm									
HI82H-05W	3.2	2.5	0.9	2.0	20	0.4				
HI82H-07W	3.8	5.0	1.0	2.5	20	0.4				
HI82H-1W	6.3	3.5	1.0	5.5	20	0.4				
HI82H-2W	10.2	5.1	1.0	9.5	20	0.4				

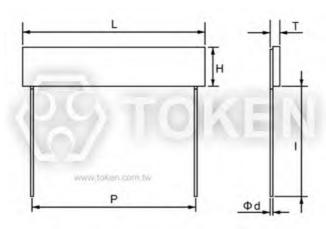
Note: L = Length, H = Width, T = Thickness, I = Length of steel wire, d = Wire diameter \circ

 $P = Standard lead spacing (Other spacing possible by bending) \circ$

HI82T High-po	HI82T High-power voltage resistor									
Part Number	L ± 1mm	H ± 1mm	$T \pm 0.5$ mm	P ± 2mm	I ± 3mm	d ± 0.1mm				
HI82T-0125W	8	3.5	2	5.7	10	0.6				
HI82T-025W	10	5	2	7.7	10	0.6				
HI82T-04W	25	5	2	22.5	20	0.6				
HI82T-05W	35	5	2	32	20	0.6				
HI82T-1W	30	8	2	27	20	0.6				
HI82T-2SW	25	10	2	22	20	0.6				
HI82T-2NW	22	18	2	19	20	0.6				
HI82T-2BW	45	10	3	41.5	20	0.8				
HI82T-3W	60	10	3	56.5	20	0.8				
HI82T-5W	80	20	4	76.5	40	1.0				
HI82T-10W	97	23	4	93.5	40	1.0				
HI82T-20W	100	35	4	96.5	40	1.0				
HI82T-30W	100	48	4	96.5	40	1.0				

Note: L = Length, H = Width, T = Thickness, I = Length of steel wire, d = Wire diameter \circ

 $P = Standard lead spacing (Other spacing possible by bending) \circ$



Ultra-precision high value voltage Resistor Dimensions (Unit: mm)

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HI82D Electrical Charcs.

Technical Characteristics - (HI82D)

Part Number	Power Rating P ₇₀ (W)	Working Voltage Max. (V)	Resistance Range (Ω)	Tolerance (%)	TCR ⁽¹⁾ (ppm/ ℃)	VCR ⁽²⁾ (ppm/V)
			1M - 100M	0.25/0.5/5/10	25/50/100	2ppm/V
HI82D-1W	1.0	10KV	100M - 1G	1/2/5/10/20	50/100/250	5ppm/V
11102D-1 W	1.0	10 K V	1G - 100G	5/10/20/30	250/500	20ppm/V
			100G - 1T	5/10/20/30	500/1000	100ppm/V
			1M - 100M	0.25/0.5/5/10	25/50/100	1ppm/V
HI82D-1BW	1.2	20KV	100M - 1G	1/2/5/10/20	50/100/250	2ppm/V
1102D-1DW	1.2	20 K V	1G - 100G	5/10/20/30	250/500	10ppm/V
			100G - 1T	5/10/20/30	500/1000	50ppm/V
			1M - 100M	0.25/0.5/5/10	25/50/100	1ppm/V
			100M - 1G	1/2/5/10/20	25/50/100	1ppm/V
HI82D-3W	3.0	30KV	1G - 100G	5/10/20/30	100/250	5ppm/V
			100G - 1T	5/10/20/30	250/500	25ppm/V
			1T - 10T	10/20/30	500/1000	100ppm/V

Note:

- (1) TCR 25/50: Temperature range +25°C \sim +85°C; (2) The voltage coefficient is measured between 10V and 100V.
- Operating Voltage = $\sqrt{(P * R)}$, or Max. Operating Voltage listed in above table whichever is lower.
- Optional specifications on request.

Environmental Characteristic

Continuous operating voltage	• •	$V = \sqrt{(P * R)}$, or Max. Operating Voltage listed in above table				
	whichever is lower.					
Measuring voltage		oltage is 10V (50V for values >1G).				
Tricasuring voltage	Different voltages on					
	Temperature range +2	5°C ~+125°C				
TCR ppm/℃	TCR25/50					
	Values above 1G: +25	Values above 1G: $+25^{\circ}$ C $\sim +85^{\circ}$ C.				
Operating temp. range	-55°C ~+125°C	-55°C ~+125°C				
Climatic category to EN 60068-1	55/125/56					
	Lacquer coating. Resignee recommended for clear	Lacquer coating. Resistant to most solvents. Isopropyl alcohol				
Humidity-/contact protection		methylene choloride. Avoid mechanical stress to				
	coating.	metayiene enororae. Avoid meenamear suess to				
Stabilitary Stanger 125°C /1000Hag	≤10G	>10G				
Stability: Storage 125°C/1000Hrs	<1%	<2%				
Stability of Mary walters /1000Has	≤10G	>10G				
Stability at Max. voltage/1000Hrs	<1%	<2%				

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HI82H Electrical Charcs.

Technical Characteristics - (HI82H)

Part Number	Power Rating P ₇₀ (W)		g Voltage x. (V) untrimmed	Resistance Range (Ω)	Tolerance (%)	TCR ⁽¹⁾ (ppm/°C)	VCR ⁽²⁾ (ppm/V)		
				1M - 100M	1/2/5/10	TC25/50/100	<50ppm/V		
			>100M - 500M	2/5/10/20	TC50/100/250	<100ppm/V			
				>500M - 1G	5/10/20	TC100/250	<100ppm/V		
HI82H-05W	0.5	300	1000	>1G - 10G	5/10/20/30	TC250/500	<500ppm/V		
				>10G - 100G	5/10/20/30	TC500/1000	<1000ppm/V		
				>100G - 1T	-	-	-		
				1M - 100M	2/5/10	TC50/100	<50ppm/V		
			>100M - 500M	5/10/20	TC100/250	<100ppm/V			
	0.7	200	500	>500M - 1G	5/10/20	TC100/250	<100ppm/V		
HI82H-07W	0.7	300	300	>1G - 10G	10/20/30	TC250/500	<500ppm/V		
				>10G - 100G	10/20/30	TC500/1000	<1000ppm/V		
				>100G - 1T	-	-	-		
				1M - 100M	1//10	TC25/50/100	<10ppm/V		
				>100M - 500M	1/2/5/10/20	TC25/50/100	<25ppm/V		
HI82H-1W	1.0	1200	2500	>500M - 1G	1/2/5/10/20	TC100/250	<25ppm/V		
1110211-1 VV	1.0	1200	2300	>1G - 10G	2/5/10/20	TC100/250	<100ppm/V		
				>10G - 100G	5/10/20/30	TC250/500	<250ppm/V		
				>100G - 1T	10/20/30/50	TC500/1000	<500ppm/V		
				1M - 100M	1//10	TC25/50/100	<5ppm/V		
HI82H-2W				>100M - 500M	1/2/5/10/20	TC25/50/100	<10ppm/V		
	2.0	4000	6000	>500M - 1G	1/2/5/10/20	TC25/50/100	<10ppm/V		
	2.0	7000	0000	>1G - 10G	2/5/10/20	TC50/100	<25ppm/V		
				>10G - 100G	5/10/20/30	TC100/250	<100ppm/V		
			>100G - 1T	5/10/20/30	TC250/500	<250ppm/V			

Note:

- (1) TCR 25/50: Temperature range +25°C ~ +85°C; (2) The voltage coefficient is measured between 10V and 100V.
- Operating Voltage = $\sqrt{(P * R)}$, or Max. Operating Voltage listed in above table whichever is lower.
- Optional specifications on request.

Environmental Characteristic

Continuous Operating Voltage	$V = \sqrt{(P * R)}$, or Max. O	perating Voltage listed in	n above table whichever is				
commutation operating votage	lower.	lower.					
Maaguring Valtage	Standard measuring voltage is	s 10V (50V for values >	1G).				
Measuring Voltage	Different voltages on request.	Different voltages on request.					
	Temperature range +25°C ~ ·	+125℃					
TCR ppm/℃	TCR25/50	TCR25/50					
	Values above 1G: $+25^{\circ}$ C $\sim +85^{\circ}$ C.						
Operating Temperature Range	-55°C ~+125°C						
Climatic Category to EN 60068-1	55/125/56						
	Lacquer coating. Resistant to	Lacquer coating. Resistant to most solvents. Isopropyl alcohol recommended for					
Humidity-/Contact Protection	cleaning;						
	Do not use acetone or methyl	ene choloride. Avoid me	echanical stress to coating.				
Stability: Storage 125°C/1000Hrs.	≤1G	≤10G	>10G				
Stability. Storage 123 C/10001115.	<1%	<2%	<5%				
Stability at May valtage/1000Hmg	≤1G	≤10G	>10G				
Stability at Max. voltage/1000Hrs.	<0.5%	<1%	<2%				

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HI82T Electrical Charcs.

Technical Characteristics - (HI82T)

Part Number	Power Rating P ₇₅ (W)	Working Voltage Max. (V)	Resistance Range (Ω)	Tolerance (%)	TCR
HI82T-0125W	1/8W	2KV	1 ~ 500M		
HI82T-025W	1/4W	4KV	1 ~ 500M		
HI82T-04W	2/5W	10KV	1 ~ 500M		±100ppm/°C
HI82T-05W	1/2W	15KV	1 ~ 500M		
HI82T-1W	1W	15KV	1 ~ 500M		
HI82T-2SW	2W	20KV	1 ~ 500M		
HI82T-2NW	2W	20KV	1 ~ 500M	$\pm 0.5\% \sim \pm 5\%$	
HI82T-2BW	2W	20KV	1 ~ 500M		
HI82T-3W	3W	25KV	1 ~ 500M		
HI82T-5W	5W	30KV	1 ~ 500M		
HI82T-10W	10W	35KV	1 ~ 500M		
HI82T-20W	20W	35KV	1 ~ 500M		
HI82T-30W	30W	35KV	1 ~ 500M		

Note:

- TCR @25°C (25°C ~+105°C). TCR ±15ppm/°C on request.
- Operating Voltage = $\sqrt{(P * R)}$, or Max. Operating Voltage listed in above table whichever is lower.
- Optional specifications on request.

Environmental Characteristic

Continuous Operating Voltage	$V = \sqrt{(P *)}$	$V = \sqrt{(P * R)}$, or Max. Operating Voltage listed in above table					
Continuous Operating Voltage	whichever is l	whichever is lower.					
Measuring Voltage	Standard mea	suring voltage is 10V (5	0V for values >1G).				
Wieasuring voltage	Different volt	ages on request.					
	Temperature i	cange $+25^{\circ}\text{C} \sim +105^{\circ}\text{C}$					
TCR ppm/℃	TCR 25/50						
	Values above	1G: +25°C ~+105°C.					
Operating Temperature Range	-55°C ~ +225	-55°C ~+225°C					
Climatic Category to EN 60068-1	55/125/56						
Insulation withstand voltage	1000VDC						
Insulation resistance	≥ 10GΩ						
H 114 /G 4 / P 4 /	-	Lacquer coating. Resistant to most solvents. Isopropyl alcohol recommended for cleaning;					
Humidity-/Contact Protection	Do not use ac	Do not use acetone or methylene choloride. Avoid mechanical stress to					
	coating.	·					
Stability: Storage 125°C/1000Hrs.	≤1G	≤10G	>10G				
Stability: Storage 125 C/1000 IIIs.	<1%	<2%	<5%				
Stability at May valtage/1000Hrs	≤1G	≤10G	>10G				
Stability at Max. voltage/1000Hrs.	<0.5%	<1%	<2%				

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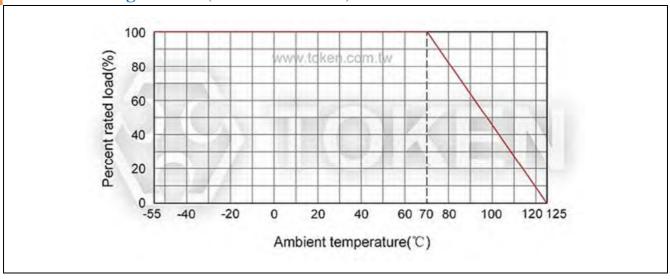
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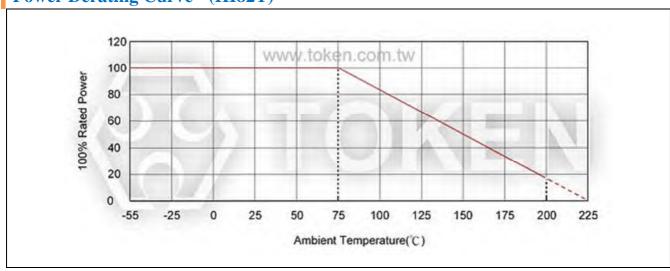


▶ Power Derating Curve

Power Derating Curve - (HI82D & HI82H)



Power Derating Curve - (HI82T)



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Advance Technique

Advance Technique of Non-Inductive & Serpentine Pattern (HI82)

Non-Inductive Performance:

- HI82 Non-Inductive Design which uses a serpentine resistive pattern that offers for zigzagging lines to carry current in opposite directions, thereby achieving maximum neutralization of flux fields over the entire length of the resistor.
- This efficient non-inductive construction without derating of any performance advantages is ideal for applications where high frequency is required.



Serpentine Pattern Screen Printing Design:

- Type High Voltage HI82 Precision Resistors combine Token's Non-Inductive serpentine pattern, high thru-put screen printed silicone coating.
- The alignment of the gap in the serpentine resistor pattern with the gap in the coating pattern provides a complete encapsulation of the resistor element.
- The cap and lead assemblies are pressed onto the resistor core, finishing the resistor and providing rugged terminal attachment.

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Order Codes

Order Codes (HI82D) - Ultra-Precision High-Voltage High Value Resistors

HI82D		1W	1G			F	E		
Part Number	Rated Power (W)		Resistance Value (Ω)		Resist	Resistance Tolerance		TCR (ppm/°C)	
HI82D	1W	1.0W	1M1	1.1ΜΩ		(%)	С	±25ppm/°C	
	1BW	1.2W	110M	110ΜΩ	С	±0.25%	D	±50ppm/°C	
	3W	3.0W	1G5	1.5GΩ	D	±0.5%	E	±100ppm/°C	
			10G	10GΩ	F	±1%			
			<u> </u>		J	±5%	L	±250ppm/°C	
					K	±10%	I	±500ppm/°C	
					M	±20%	R	±1000ppm/℃	
					N	±30%			

Order Codes (HI82H) - Conventional Precision High-Voltage High-Resistance Resistors

НІ82Н	2W		1G		F		E		
Part Number	Rated Power (W)		Resistance Value (Ω)		Resist	Resistance Tolerance		TCR (ppm/°C)	
HI82H	05W	0.5W	1M1	1.1ΜΩ	(%)		С	±25ppm/°C	
	07W	0.7W	110M	110MΩ	F	±1%	D	±50ppm/°C	
	1W	1.0W	1G5	1.5GΩ	G	±2%	E	±100ppm/°C	
	2W	2.0W	10G	10 G Ω	J	±5%	L	±250ppm/°C	
			1T	1ΤΩ	K	±10%		±500ppm/°C	
				M	±20%	-			
					N	±30%	R	±1000ppm/℃	

Order Codes (HI82T) - High-Power Voltage Resistors

	•	,		O				
HI82T	30W		500M		F		E	
Part Number	Rated P	ower (W)	Resista	ance Value (Ω)	Resistance Tolerance		TCR (ppm/°C)	
HI82T	0125W	1/8W	10	10Ω	(%)		Е	±100ppm/°℃
	04W	2/5W	1M1	1.1ΜΩ	D	±0.5%		±15ppm/°C
	2BW	2W	110M	110ΜΩ	F	±1%	C5	on request
	10W	10W	500M	500ΜΩ	J ±5%			
	30W	30W						

• Note: If no requirements for TCR, (HI82D), (HI82H) and (HI82T) measuring voltage and taping are given, the standard value(highest value in table) will be supplied, measuring voltage of 10V.



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Carbon Composition Resistors (CCR)

Product Introduction

High pulse withstanding carbon composition resistors handle big peaks and pulses.

Features:

- Low inductance
- Solid rod carbon composition
- Power rating 1/4W and 2W
- Resistance range $1.8\Omega \sim 22K\Omega$
- Resistance tolerance $J(\pm 5\%)$, $K(\pm 10\%)$ and $M(\pm 20\%)$
- High pulse withstanding and high energy capability
- Products with Pb-free Terminations and RoHS compliant

Applications:

- Strobe Lighting
- High Power Lighting
- Medical defibrillators
- Welding, Automotive
- Inrush Current Limiting
- High Voltage Power Supplies
- Protection (e.g. Discharge Circuits, Surge Protection)

The high pulse withstanding capability of the CCR series of carbon composition resistors from Token Electronics offers designers a compact solution for applications involving high voltages and high-energy pulses.

Though, many resistor manufacturers claim to offer carbon composition replacements. However, these wire wound or thick film alternatives do not fully match the pulse performance and low inductance of carbon composition.

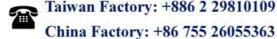


Token's CCR series now offers the industry a carbon composition resistor made up of a solid rod of conductive composite material, the chemical composition of which is altered to produce different resistance values.

The main advantage of carbon composition is their pulse handling capability. This is due to the fact that the entire rod conducts and so the thermal mass is far higher, which results in a higher energy capability. Due to the need for higher peak voltages, the CCR range is perfect for vehicle ignition system applications, medical monitoring equipment and as output resistors in defibrillators.

The standard carbon composition CCR resistor offers a power rating of 1/4W, 1/2W, 1W and 2W at 25 °C and is made up of a solid rod of conductive composition material, which can be altered to produce different resistance values. With a typical resistance range of $1.8\Omega \sim 22K\Omega$, resistance tolerance is $J(\pm 5\%)$, $K(\pm 10\%)$ and $M(\pm 20\%)$. Resistors with 5%, 10% and 20% tolerance have four bands indicating value and tolerance in accordance with IEC62.

Our custom solutions are designed to address your need for technical and economic success in a timely manner. Contact us with your specific needs. For more information, please link to Token official website "High Voltage Resistors".

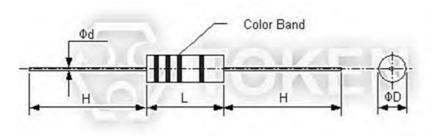




Dimensions

Dimensions (Unit: mm) (CCR)

Type	Power Rating	L		L		L		ФЪ	Н	Φd
CCR	1/4W	6.3	+1.0	2.3±0.3	27±2	0.60±0.02				
CCR	1/2W	9.5	+0.5	3.5±0.3	27±2	0.70±0.02				
CCR	1W	15	+1.5	6.0±0.3	28±2	0.80±0.02				
CCR	2W	18	+0.5	8.0±0.3	27±2	1.00±0.02				



Unit: mm

Carbon Composition (CCR) Dimensions (Unit: mm)

Ratings Specifications

Ratings Specifications (CCR)

Type	Power Rating	Resistance Range	Tolerance E12,E24	Max Working voltage	Max overload Voltage	Rated Ambient Temp.	Operating Temp. Range
CCR	1/4W	2.2Ω ~ 12MΩ		250V	400V	+70°C	-55°C ~+125°C
CCR	1/2W	$2.2\Omega \sim 22M\Omega$	J(±5%) K±10% M±20%	350V	700V	+70°C	-55°C ~+125°C
CCR	1W	2.2Ω ~ 22ΚΩ		500V	1000V	+70°C	-55°C ~+125°C
CCR	2W	1.8Ω ~ 10ΚΩ		500V	1000V	+70°C	-55°C ~+125°C

• Rated Voltage = $\sqrt{\text{Power Rating} * \text{Resistance Value}}$ or Max. Working voltage, whichever is lower.

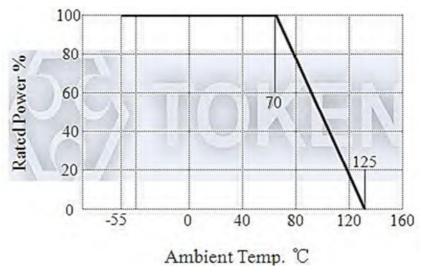
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Derating Curve

Derating Curve (CCR)



(CCR) Derating Curve

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Performance

Performance (CCR)

Description		Performance Req	uirements		Test Method			
		Resistance Range	Change %	Resistance Value				
			-40~+20°C	+20~+100°C				
Resistance		<1KΩ	±6.5%	±5.0%	T T.			
Temperature		1.1ΚΩ ~10ΚΩ	±10%	±6.0%	Test Temperature +20°C /-40°C /+20°C /+100°C /+20°C			
Coefficient		11ΚΩ ~100ΚΩ	±13%	±7.5%	120 € 7-40 € 7+20 € 7+100 € 7+20 €			
		11ΚΩ ~1ΜΩ	±15%	±10%				
		1.1ΜΩ ~10ΜΩ	±20%	±15%				
		>11MΩ	±25%	±20%				
Short-time Overload		Δ R≤±2.5%			Rate Voltage*2.5 or maximum overload voltage (the lower)5sec.			
With Standing Voltage		No flashover or breakdown			2times maximum working voltage 1 minute			
	Pulled				Load 10N 10s			
Terminal Strength	Winded	ΔR≤±2% No visible	le damage		Load 10N 4*90°			
Strength	Twisted				3*360° in opposite direction			
Resistance to vibration		No visible damage			10~50Hz 3 direction 2 hours each			
Solder-heat R	Resistance	ΔR≤±5% Marks legible, no visible damage			350°C 4mm from the body,3 seconds			
Solderability		At least 95% if the by new solder, no f		ace must be covered d.	235°C 2mm from the body,2 seconds			
Temperature Cycle		ΔR≤±2% No visible damage			-40°C (30min.)/85°C (30min.)5 cycles			
Humidity		ΔR≤±10% No visil	ble damage		40℃ 95% RH 240 hours			
Load Life		ΔR≤±10% No visible damage, marks legible			Rated voltage or maximum working voltage, 1.5 hours on, 0.5 hours off, 40°C 1000 hours			

Order Codes

Order Codes (CCR)

CCR	1/2W	120R		K		P	
Part Number	Rated Power	Resistance Value (Ω)		Resistance Tolerance		Package	
CCR	(W)	2R2	2.2Ω	(%)		P	Bulk
	'	120R	120Ω	J	±5%		
		1M2	1.2ΜΩ	K	±10%		
		22M	22ΜΩ	M	±20%		

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Tubular High Voltage Precision Divider Resistors (HI80M)

▶ Product Introduction

Cylindrical Thick Film High-Voltage Resistor Dividers Provide Accuracy And Stability.

Features:

- High precision, Non-Inductance design.
- High voltage, Wide range of resistance.
- Custom design services. RoHS compliant.

Applications:

- Pulse Modulator, Radar Pulse Forming Network, Impulse Voltage Generator.
- X-ray/Imaging Equipment, and EMI lightning suppression, Electric Arc Furnace Damping.
- Capacitor Arc Suppression Circuit, Energy Research, High Voltage Buffer Circuit.

Token Electronics is further expanding its solutions for challenging applications and introducing thick-film precision resistor dividers for high-voltage measurement circuits. The new (HI80M) was introduced to meet the growing demand in the medical, energy, industrial and instrumentation markets.

Thick film technology allows high resistance values to be printed on flat or cylindrical substrates. Not only can high resistance be obtained, but a high voltage can be applied to the thick film product with almost no change in resistance value. Many thick film resistors are printed using a serpentine pattern. This pattern helps reduce inductance and is the first choice for stable frequency applications.



As new industries expand, so does the demand for such components. Applications such as portable defibrillators, high-voltage PSUs, on-board instruments, TWT power supplies, radar systems, X-ray systems, analytical equipment, and high resolution CRT displays require components with tight tolerances, leading temperature coefficient (TCR), load life stability and extremely high impedance values to provide optimum space, weight and cost combinations. Package.

The Cylindrical (HI80M) of high quality, high voltage, versatile, non-inductive, thick film precision dividers available from Token Electronics. The (HI80M) divider features with voltage handling capability of up to 80 KVdc and has an operating temperature range of -55°C to +125°C, wide resistance range $2M\Omega$ to $1G\Omega$ with Resistive Ratio R2/(R1+R2) 1:1000 to 1:20000, and power up to 41W.

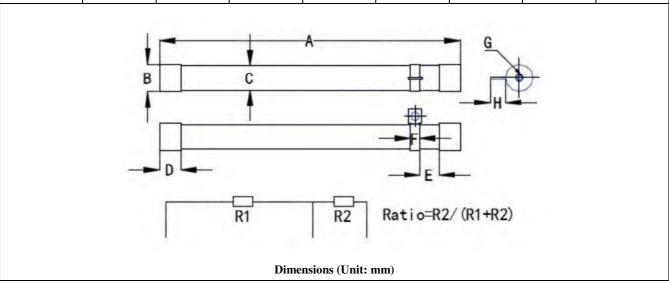
The (HI80M) conforms to the RoHS directives and Lead-free. To assist with your specifying high voltage divider application, please contact Token Electronics. We can offer high voltage divider combinations and solutions based on high voltage resistor sector in the catalog, or use our sophisticated features to provide higher accuracy in matching resistor sets. Customed design, and tighter tolerances are available on request. Or link to Token official website "High Voltage Resistors" to get more information.



Dimensions

Cylindrical High Voltage Precision Divider Resistors (HI80M) Dimensions

Type	A±2	B±0.2	C±0.5	D±2	E±1	F±0.5	G	H±2
HI80M-156	156	14.5	13.5	10	8.5	5	M4	10
HI80M-310	310	33	32	14	40	7	M6	10



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Electrical Characteristics

Electrical Characteristics - (HI80M)

Item	Specifications								
Part Number]	HI80M-156		HI80M-310					
Power (W)(40°C)		12W		41W					
U Max Working Voltage (V)		40KVDC			80KVDC				
Resistance Range (R) (R1+R2)		2M~1G		5M~1G					
Absolute TCR (ppm/°C) (25 °C ~85°C)	±50ppm/ ±100ppm	±25ppm	±15ppm	±50ppm/ ±100ppm	±25ppm	±15ppm			
Relative TCR (ppm/°C) (25°C ~85°C)	±25ppm	±15ppm	±10ppm	±25ppm	±15ppm	±10ppm			
Absolute Resistance Tolerance (%)	±0.25%~±5%	±0.25%~ ±5%	±0.25% ~ ±5%	±0.25%~±5%	±0.25%~ ±5%	±0.25%~ ±5%			
Relative Resistance Tolerance	±0.25%~	±0.1%~	±0.1%~	±0.25%~	±0.1%~	±0.1%~			
(%)	±0.5%	±0.5%	±0.5%	±0.5%	±0.5%	±0.5%			
Insulation Voltage (V)			>100	0VDC					
Resistive Ratio: R2/(R1+R2)			1:1000 to	1:20000					
Operating Temperature Range (°C)	-55°C ~+125°C								
Coated	Silicone								
Terminal	Nickel plated copper cap								
Overload	5 times of Rated Power do not exceed 1.5UMax 5s, R≤±(0.2%+0.05Ω)								
Load Life	1000Hrs. at Rated Power , $\Delta R \le \pm (0.5\% + 0.05\Omega)$								
Steady heat	40°C → RH≥95%, 240Hrs → ΔR≤±(0.4%+0.05Ω)								
Rapid Change of Temperature		-55 ~ 155	5°C at 5 cycles	s , ΔR≤±(0.2%+0).05Ω)				

- Working Voltage = $\sqrt{(P * R)}$ or Max. Working Voltage listed in above table whichever is lower.
- Overloading Voltage = $\sqrt{(5P*R)}$ or 1.5 * Max. Working Voltage listed in above table whichever is lower.

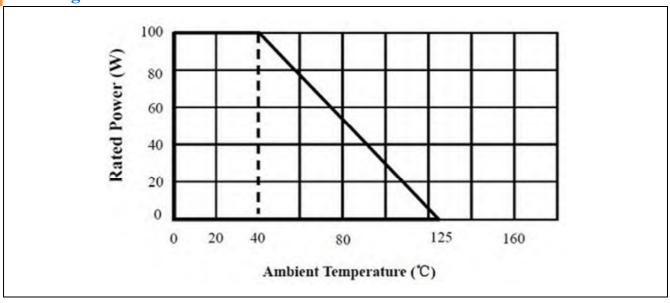
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▶ Derating Curve (HI80M)

Derating Curve



Order Codes

High Voltage Precision Divider Resistors - Order Codes (HI80M)

HI80M	-	156	C2C3		20M		5K		JD	
Part	Rated Power		TCR (ppm/°C)		$R1 + R2 (\Omega)$		R2 (Ω)		Resistance Tolerance	
Number HI80M	156	(W) 12W C1C2		100ppm absolute and 50ppm relative	20M	19.5MΩ + 5KΩ	5K 1M	5KΩ 1MΩ		±5% absolute
	310 41W C1		C1C3	100ppm absolute and 25ppm relative	30M	29.5MΩ + 5KΩ	1M5 1.5MΩ		JF	and ±1% relative
			C2C3	50ppm absolute and 25ppm relative	150M	148.5MΩ + 1.5MΩ			JD	±5% absolute and ±0.5% relative
									FC	±1% absolute and ±0.25% relative

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General Information

Cost Effective Complete Selection of High Voltage Components

Token high voltage series can be specified for use in industrial and general purpose high voltage systems, as well as a complete selection of high resistance, Hi-Meg, high-voltage, high frequency, and bulk ceramic resistors for higher average power dissipation. These High Resistance, High Frequency, High Resistance resistors combine the proven performance of Token resistance system with new cost efficient design elements and high voltage applications.

Detailed specifications, both mechanical and electrical, please contact our sales representative for more information.

High Voltage Applications

Resistors produced from Serpentine Pattern Screen Printing Design or bulk ceramic materials have displayed several key advantages in demanding high-voltage situations, including both continuous-wave and pulse applications. These include radar and broadcast transmitters, x-ray systems, defibrillators, lasers, and high-voltage semiconductor process equipment applications, where resistors must handle peak voltage anywhere from 8KV to 75KV.

Typical applications include current limit in capacitor charge/discharge, crowbar, and tube-arc circuits. In these uses, bulk ceramic resistors provide low inductance, high average power per unit size, stability at high voltage, and durability at extreme peak-power levels. Film resistors typically cannot withstand high-voltage pulse applications.

RF/Digital Loads and High-Frequency Applications

Token Non-Inductive Voltage Resistors are used extensively for high-frequency RF loads in broadcast and communication equipment because of their non-inductive characteristics. They provide excellent non-inductive power-handling capacity at frequencies up to the gigahertz range, with no sacrifice in power dissipation.

Film resistors may provide the needed non-inductive characteristics required by such RF applications, but they have size limitations and present reliability problems due to potential film burnout. This is especially true in advanced digital applications such as digital radio and TV transmitters involving pulses at high frequencies.

Application Notes

- Due to the high voltage which can appear between the end cap and any adjacent metal part, resistors should be mounted at an adequate distance from other conductors.
- An appropriate number of resistors may be screwed together as a stick to provide an assembly which will be capable to withstanding any desired voltage, providing no individual resistor is subject to a greater stress or power dissipation than is recommended in its data sheet, and that appropriate anticorona devices are fitted.
- The axial termination should not be bent closer than twice the diameter of the terminal wire from the body of the resistor.
 - When resistors are required to be potted, the preferred encapsulant is a silicone compound.

Oil Immersion

For some high voltage applications it is required to immerse the components in oil or gas to reduce the effects of corona and surface tracking. A special lacquer protected version of the resistor is available, suitable for immersion in transformer oil or SF6.



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